

iWatt

Power Management Simplified Digitally™

Advanced Digital Power Solution On Home Appliance Application

0010010101011010101010010101010101

What's New!

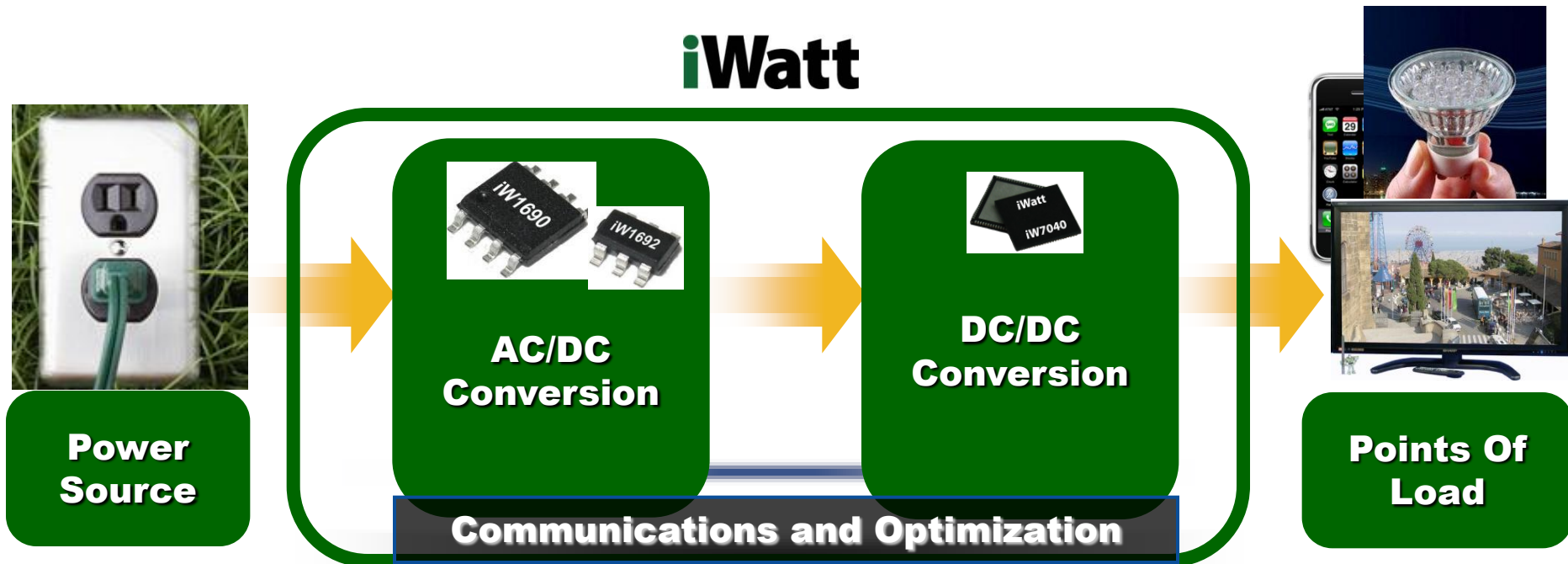
1,000,000,000

- 1 Billion ICs shipped

**iWatt
Solution
Inside**



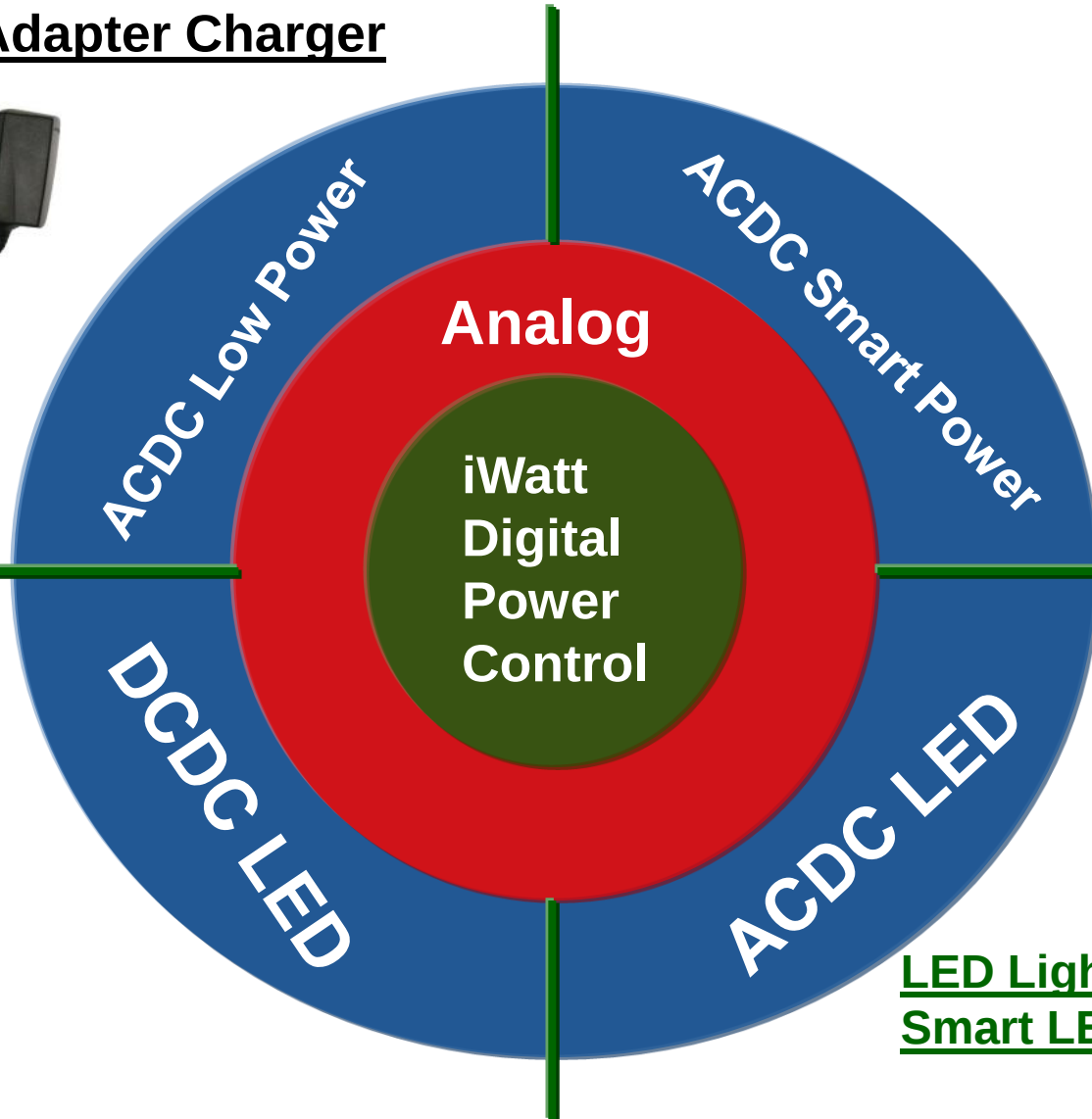
Customer-Focused Power IC Solutions Leveraging Innovative Technology and Best-in-Class Service



Universal Smart Adapter Charger



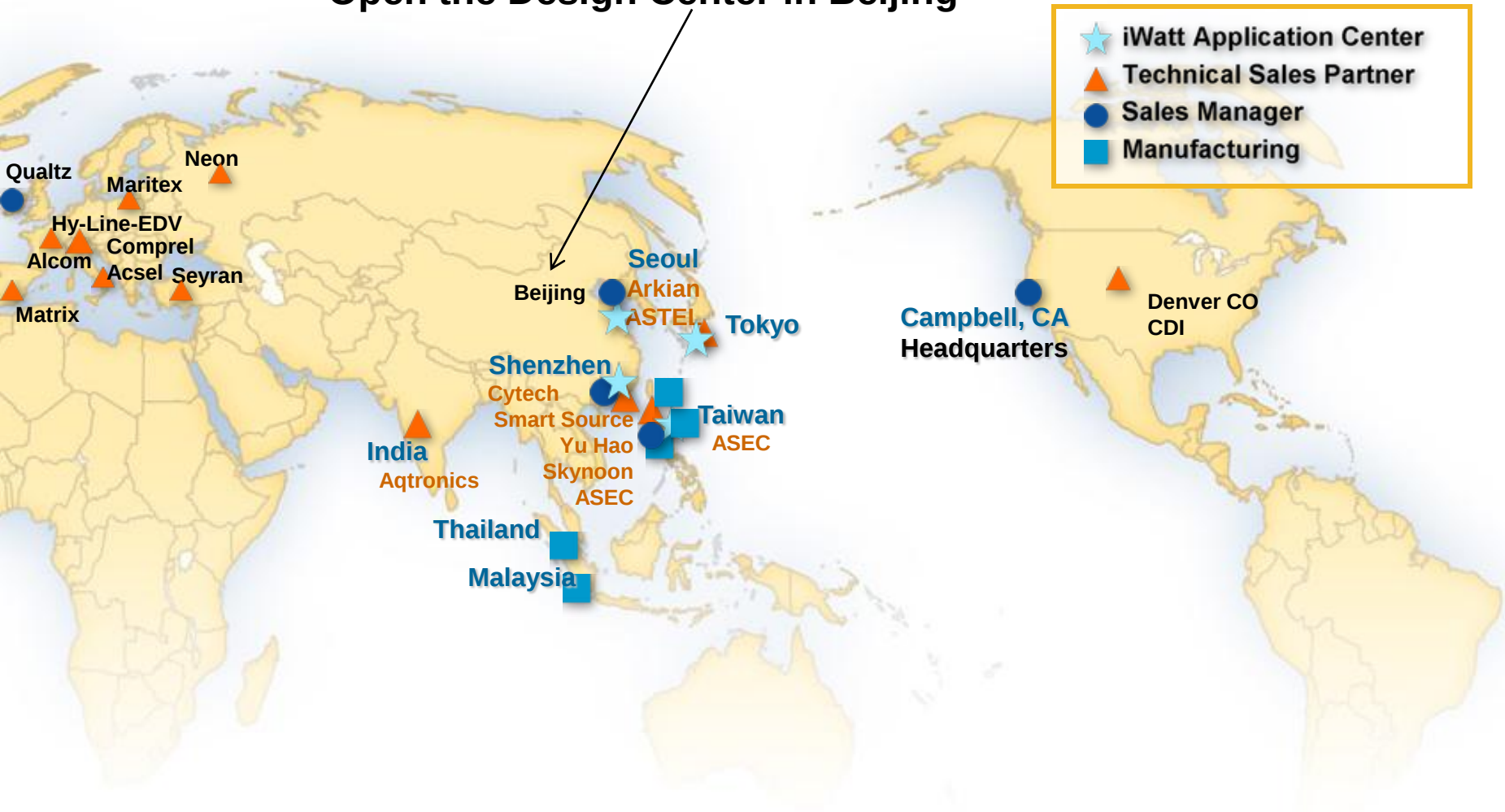
Adaptive LED Backlight Engine



LED Lighting
Smart LED controller

World-Wide Infrastructure

Open the Design Center in Beijing



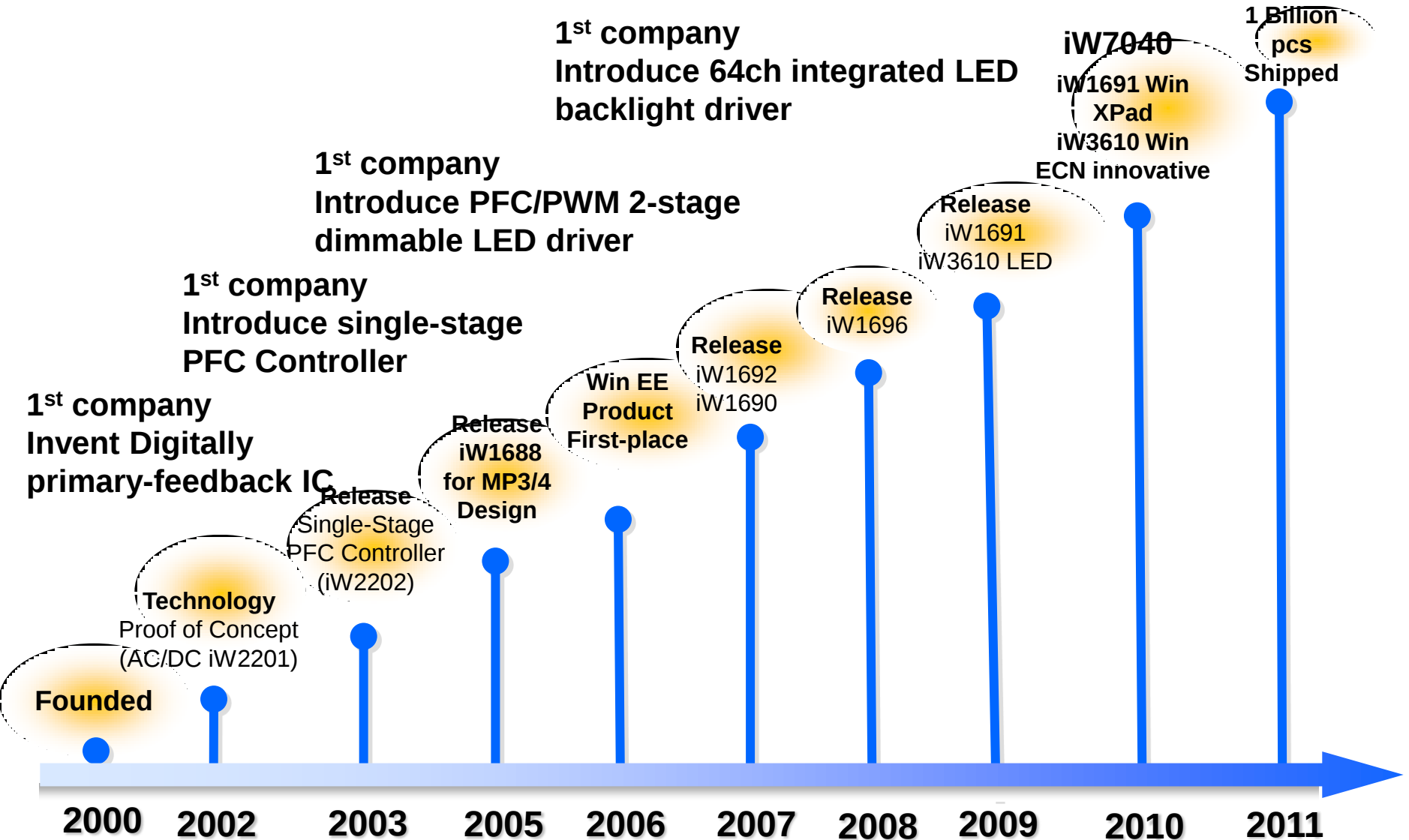
iWatt Confidential 6

iWatt IP Review & Primary Feedback Technology

Summary of iWatt Patents

- iWatt is the company who invented the primary-feedback control with digital solutions.
- The claim for digital primary feedback means to use the 1-bit comparator to detect the V_{SENSE} .
- iWatt Patent Portfolio
 - Issued Patents 44
 - Pending Applications 29
 - PCT 25

iWatt History



- ## AC/DC Charger/ Adaptor

- ## LED offline drivers:

- *iW3620, iW3610, iW3602, iW3612, iW3614*

- **Patented digital primary-feedback control technology with Tight CV regulation**
- **Patented Constant Current (CC) regulation with primary-feedback**
- **Advanced multi-layer fault protection technology**

❑ 5 Issued patents related to fly-back converter Primary-feedback constant voltage control

- 1) "Isolated power converter having primary feedback control"
6,370,039 April 9, 2002
- 2) "Transformer-coupled switching power converter having primary feedback control"
6,385,059 May 7, 2002
- 3) "PWM power converter with digital sampling control circuitry"
6,862,198 March 1, 2005
- 4) "PWM power converter controlled by transition detection of a comparator error signal"
6,900,995 May 31, 2005
- 5) "Reconstruction of the output voltage of an AC-DC power converter"
6,990,000 January 24, 2006

❑ 3 Issued patents related to primary-feedback control constant current

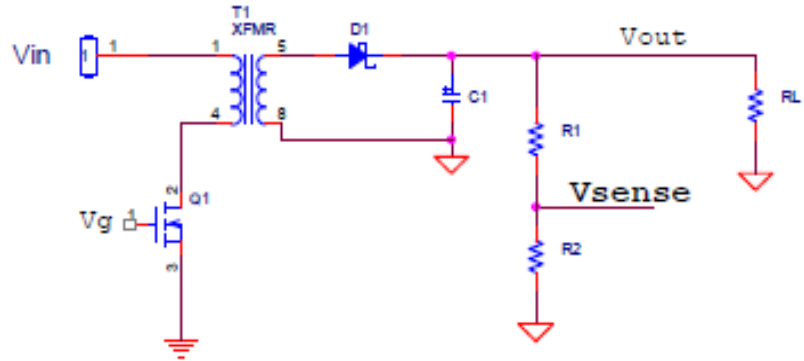
- 1) "System and method for controlling current limit with primary side sensing"
6,972,969 December 6, 2005
- 2) "System and method for input current shaping in a power converter"
6,944,034 September 13, 2005
- 3) "on-time control for constant current mode in a flyback power supply"
7,443,700 Oct 2008

❑ 1 Issued patent related to the integrated power converter

- 1) "Switching power supply packages"
6,434,021 August 13, 2002

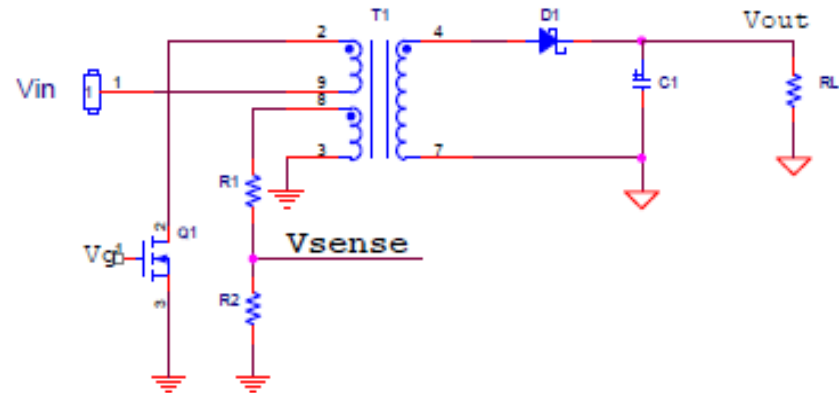
- Secondary Output Voltage Sensing

- Traditional
- Straightforward
- Need additional isolation media to transfer feedback signal to controller
- High cost , large size

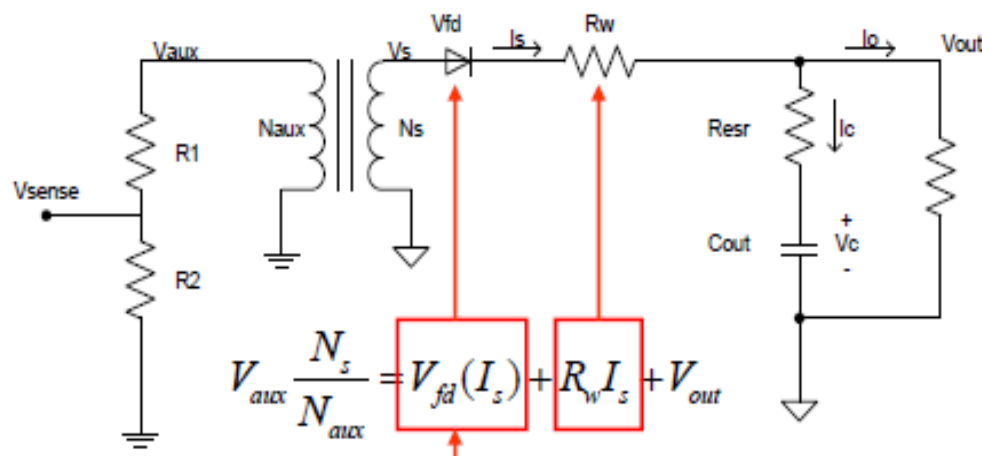


- Primary Output Voltage Sensing

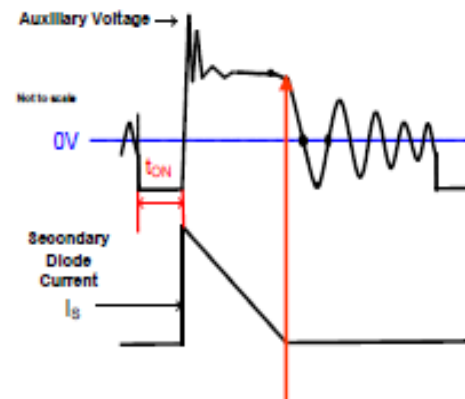
- Indirect
- Do not need additional isolation media
- Output voltage is reflected on third winding when Q1 is turns off
- Need intelligently read real time waveform



Correlation: Aux Voltage vs. Output Voltage



$$V_{aux} \frac{N_s}{N_{aux}} = V_{fd}(I_s) + R_w I_s + V_{out}$$



- The best time to sample output voltage is when the secondary current is close to ZERO, where there is no voltage drop in the PCB trace resistance R_w , and the diode forward voltage drop is minimum and can be ignored, thus

$$V_{aux} \frac{N_s}{N_{aux}} = V_{out}$$

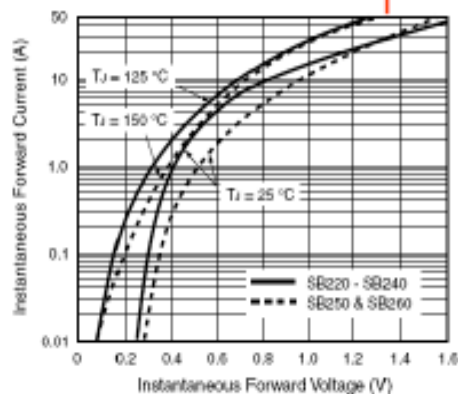
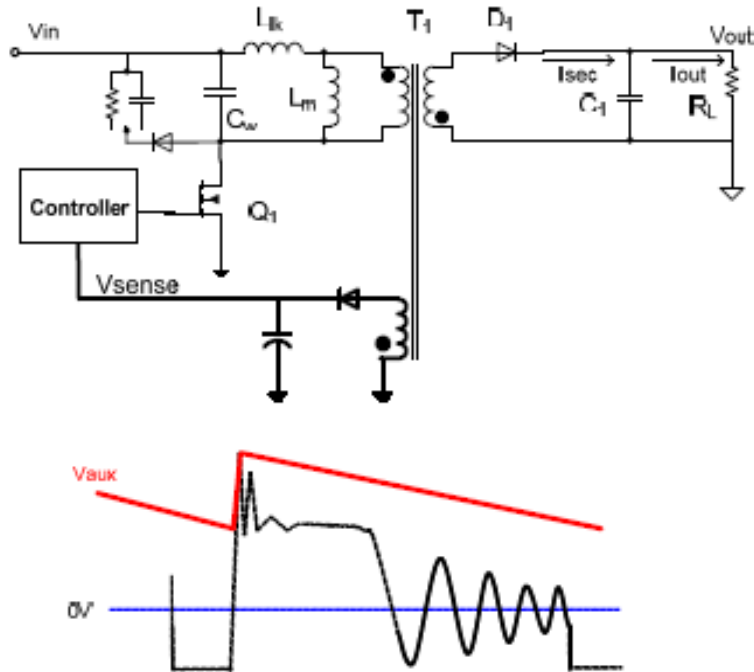
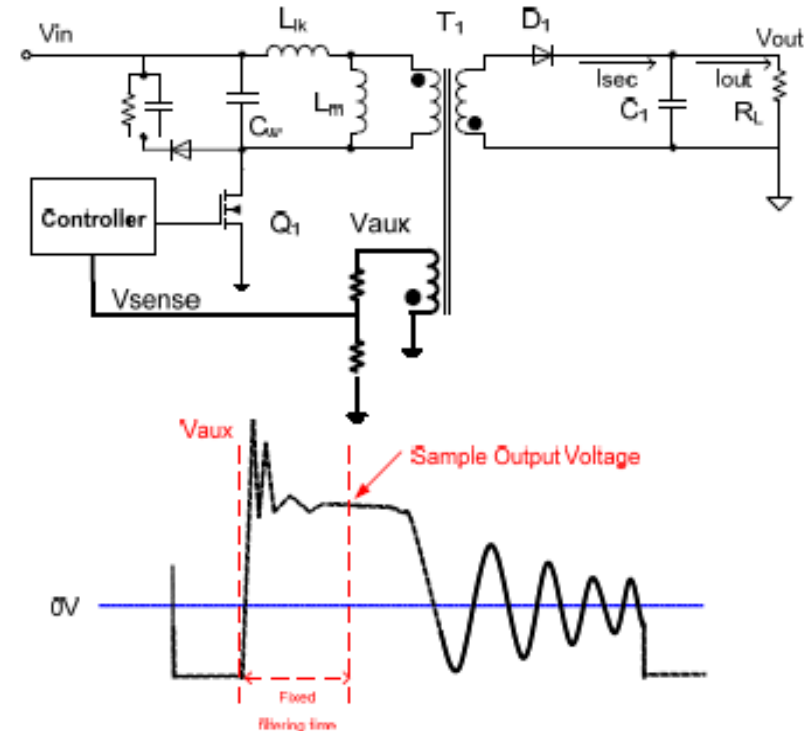


Figure 3. Typical Instantaneous Forward Characteristics

Conventional Primary Side Feedback



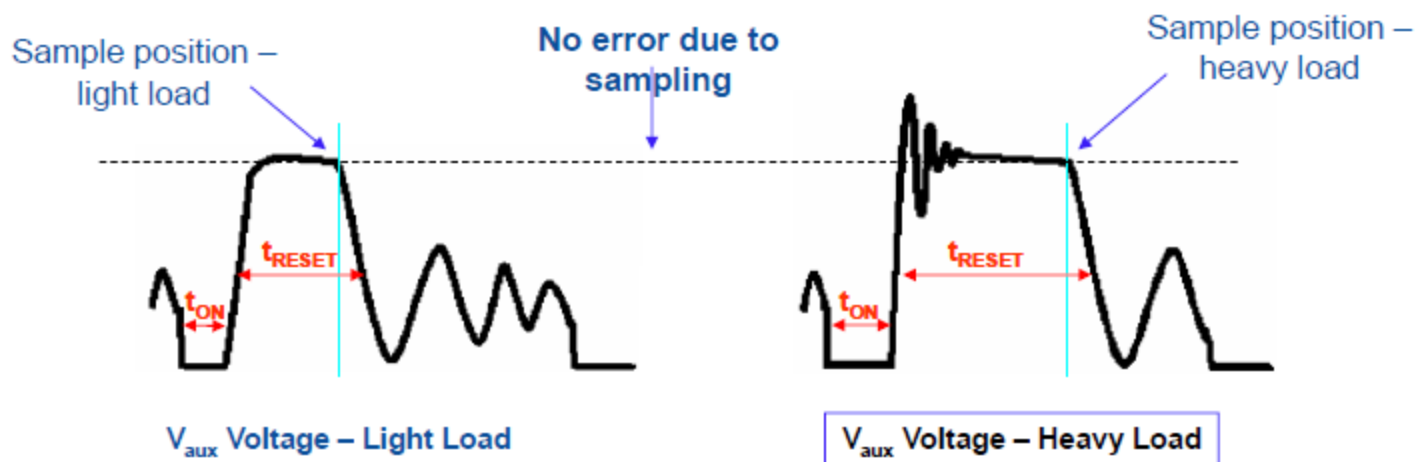
- Method 1 – peak value detection
- Problem – Ringing affects output voltage sampling



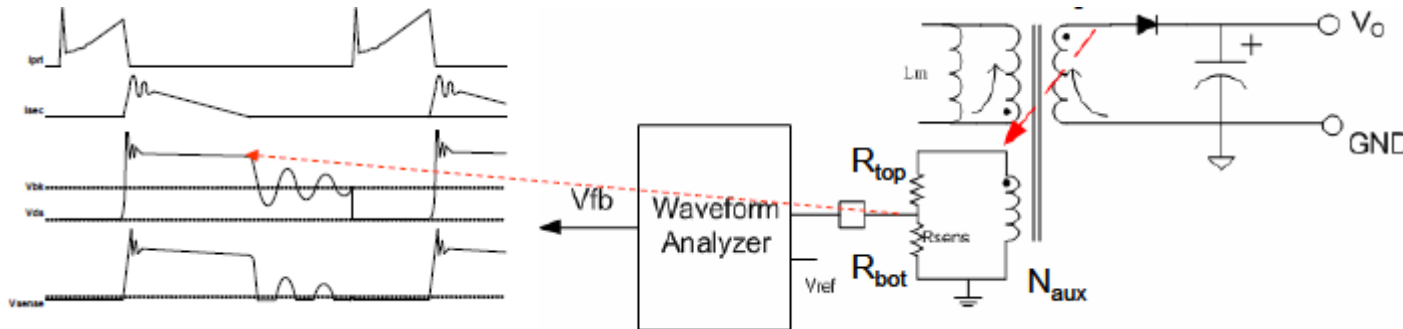
- Method 2 – sample after fixed filtering time to remove ringing impacts
- Problem – Sensed voltage varies with output current

iWatt Patented Digital Primary Feedback

- Actively searches the best location (before transformer voltage collapse) to sense output the voltage.
- Cycle by cycle response is possible because valuable data is not filtered out
- Excellent load regulation performance due to controlled sample position
- Digitally implemented in all iWatt AC/DC products



Output Voltage Regulation



- Output voltage is sampled at zero secondary current. It removes the output voltage dependence on PCB trace resistance and output rectifier forward voltage drop.
- By regulating the sensing voltage toward internal reference voltage at this particular sampling point, the output voltage is tightly regulated

→ **Achieves <+-3% CV regulation at PCB end in typical designs**

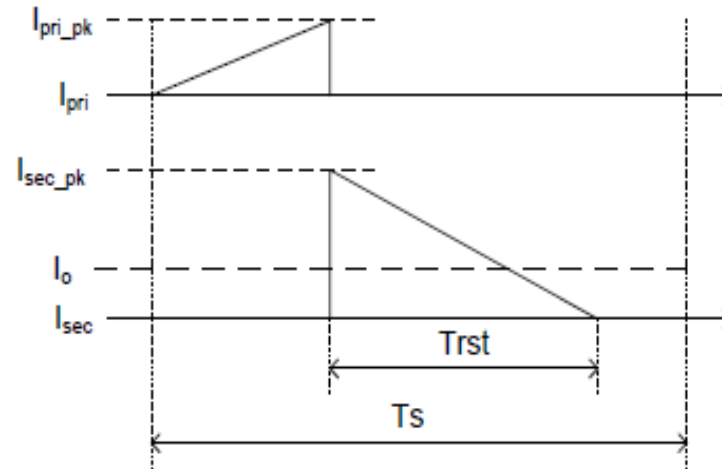
$$V_o = \frac{N_s}{N_{aux}} V_{ref} \left(1 + \frac{R_{top}}{R_{bot}} \right)$$

Cycle by Cycle O/P Current Estimation

$$I_o = \frac{I_{sec_pk}}{2} \frac{T_{rst}}{T_p}$$

$$I_{sec_pk} = I_{pri_pk} N_{ps}$$

$$I_o = \frac{1}{2} N_{ps} \frac{V_{ipk}}{R_{sense}} \frac{T_{rst}}{T_p}$$



Discontinuous Current Mode (DCM)

- Control Equation

$$V_{ipk} = K_C \frac{T_p}{T_{rst}}$$

$$I_o = \frac{1}{2} N_{ps} \frac{V_{ipk}}{R_{sense}} \frac{T_{rst}}{T_p}$$

- Output Current, setup by transformer turns ratio N_{ps} and sensing resistor R_{SENSE}

$$I_o = \frac{1}{2} N_{ps} \frac{K_C}{R_{sense}}$$

Block diagram of a current-mode control system for a buck converter. The diagram shows a power stage with an inductor L and a MOSFET. The MOSFET gate is driven by a PWM signal. The MOSFET source is connected to a sense resistor R_{ss} , which is connected to ground. The output voltage V_{ss} is taken across R_{ss} . The output current I_o is the current through the inductor. The control loop includes a feedback network with a transfer function $K_c \frac{T_p}{T_{rst}}$. The feedback signal is compared with a reference $V_{peak_set_d}$ from a DAC. The error signal is amplified by a voltage comparator and then a PWM block to generate the gate drive. The current I_o is also fed back to the DAC via a current-to-voltage converter with gain K_c / R_{ss} .

$$I_o = \frac{1}{2} N_{ps} \frac{K_c}{R_{sense}}$$

What We can Do for You?

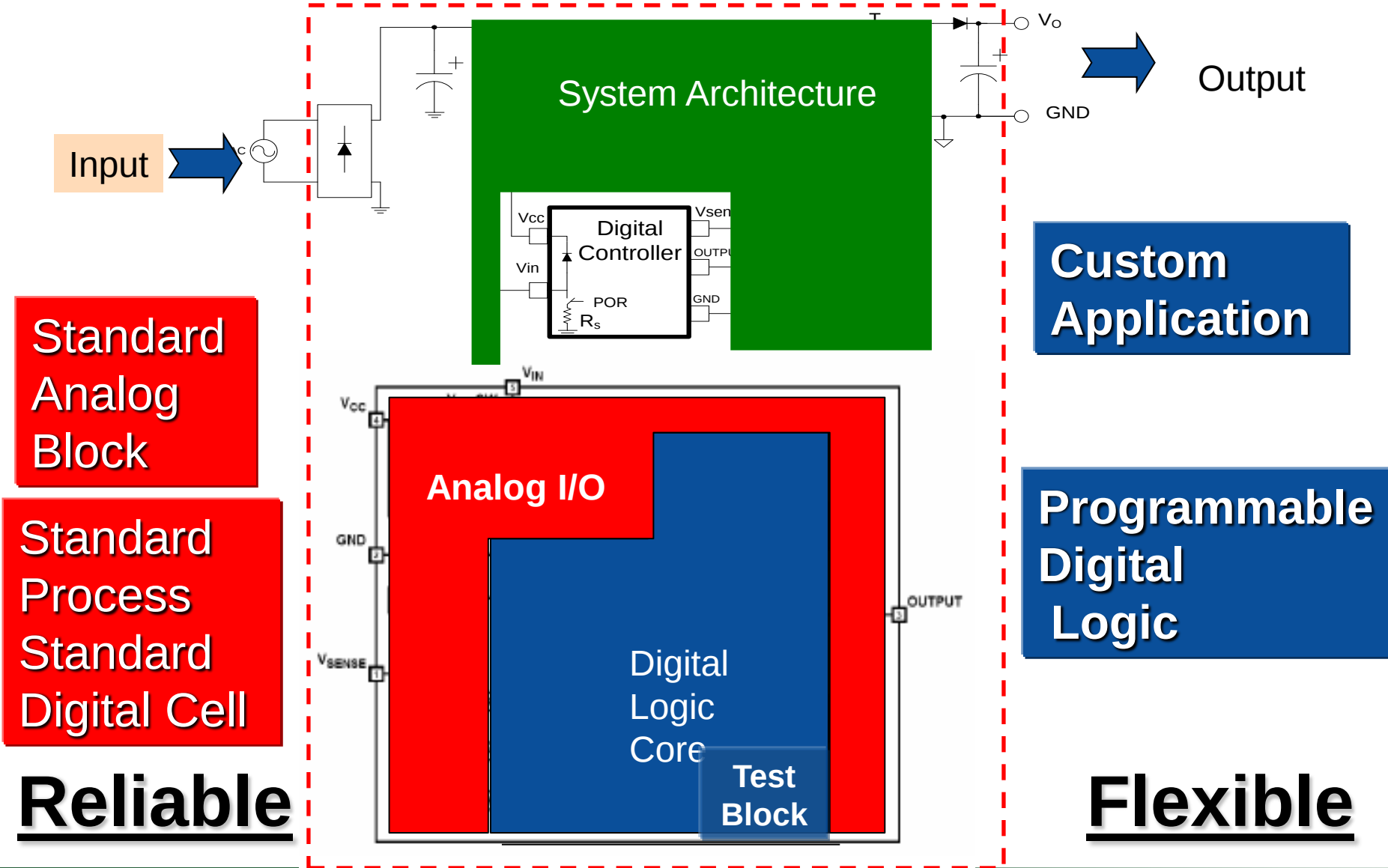
A Simple Flexible and Reliable Platform

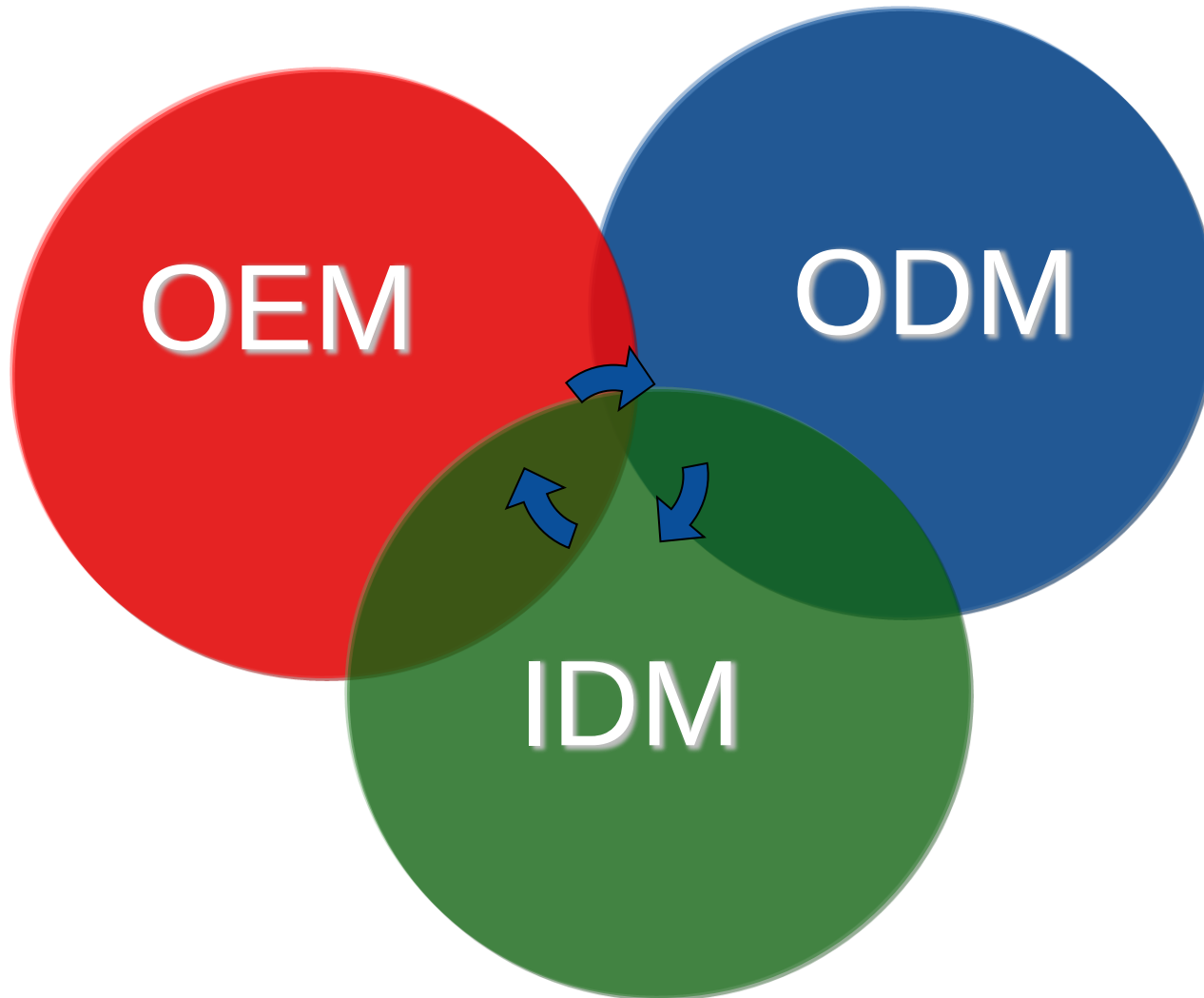
What the Next Is? 3S Adapter

- **Slim, Slim and Slim**
- **Smart, Smart and Smart**
- **Single Adapter to Support All Product**

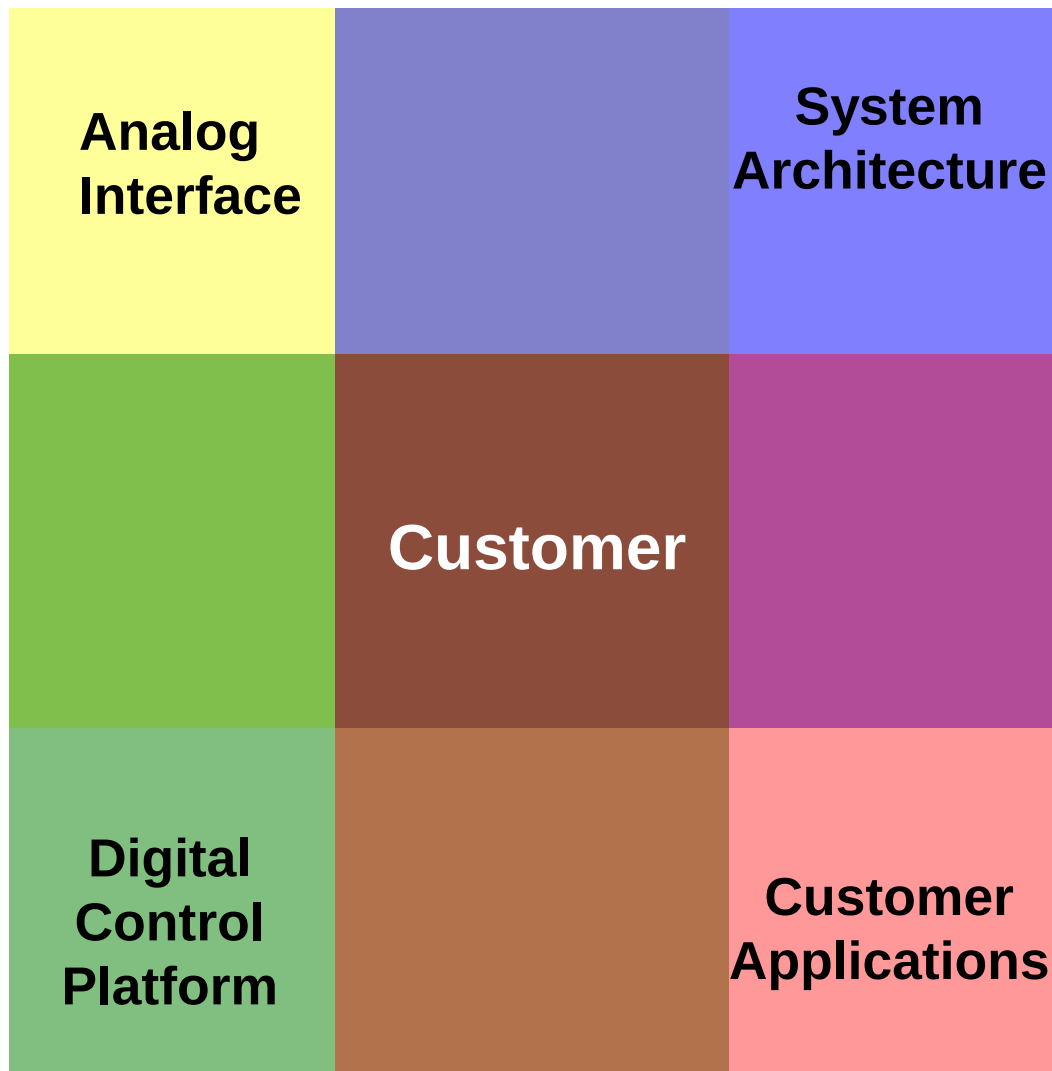
Smart Power Supply for Home Appliance

Intelligent Digital Power Control Platform



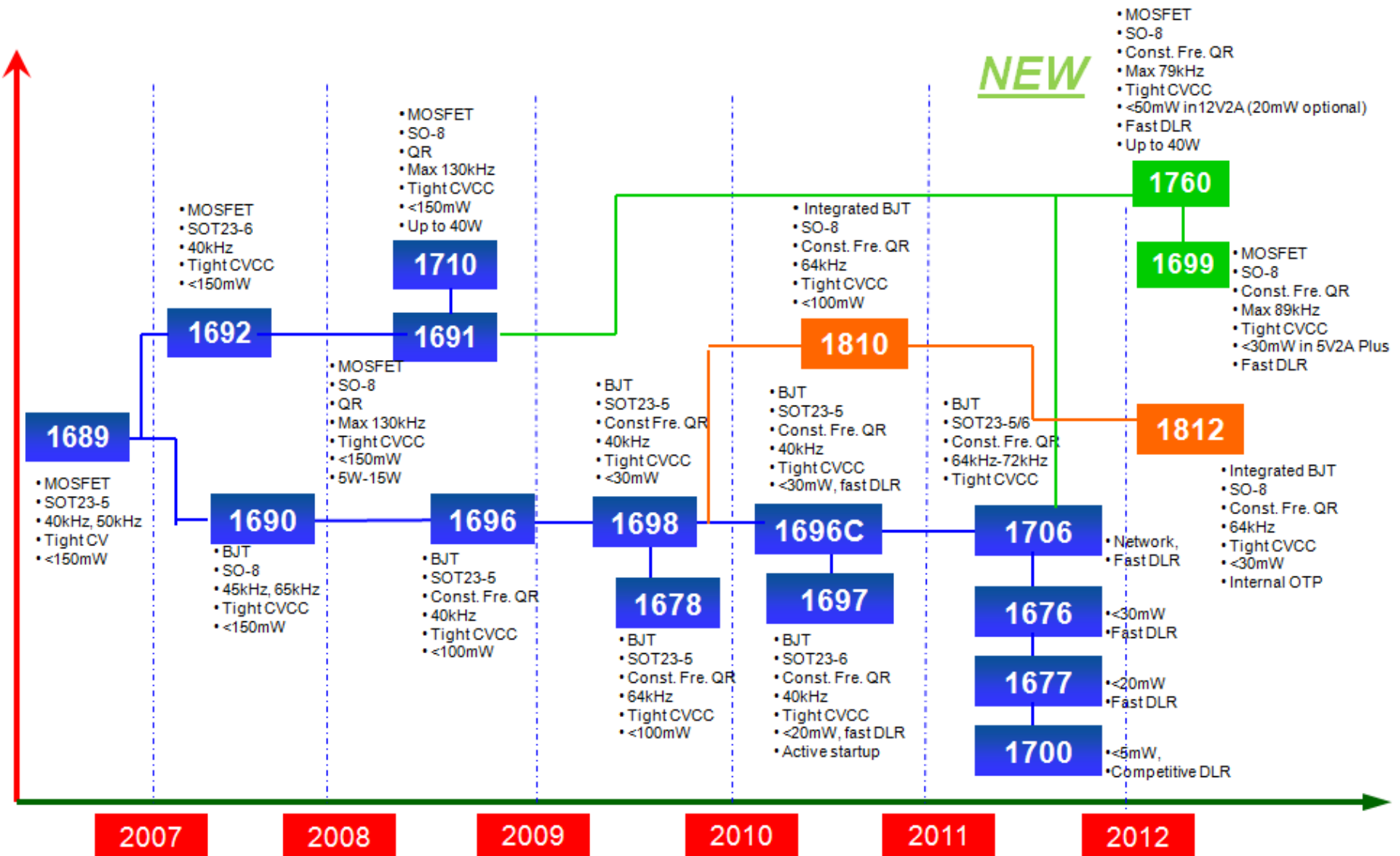


iWatt Digital Power Control Technology: Bringing It All Together



Update ACDC Product Roadmap

AC/DC Roadmap



- Reduce the BOM cost
 - New system architecture to improve efficiency
 - Reduce the component account
 - More integration
- Manufacturability
 - Easy EMI design to simplify the transformer design
 - Auto-wind transformer
- Enhance the quality by design

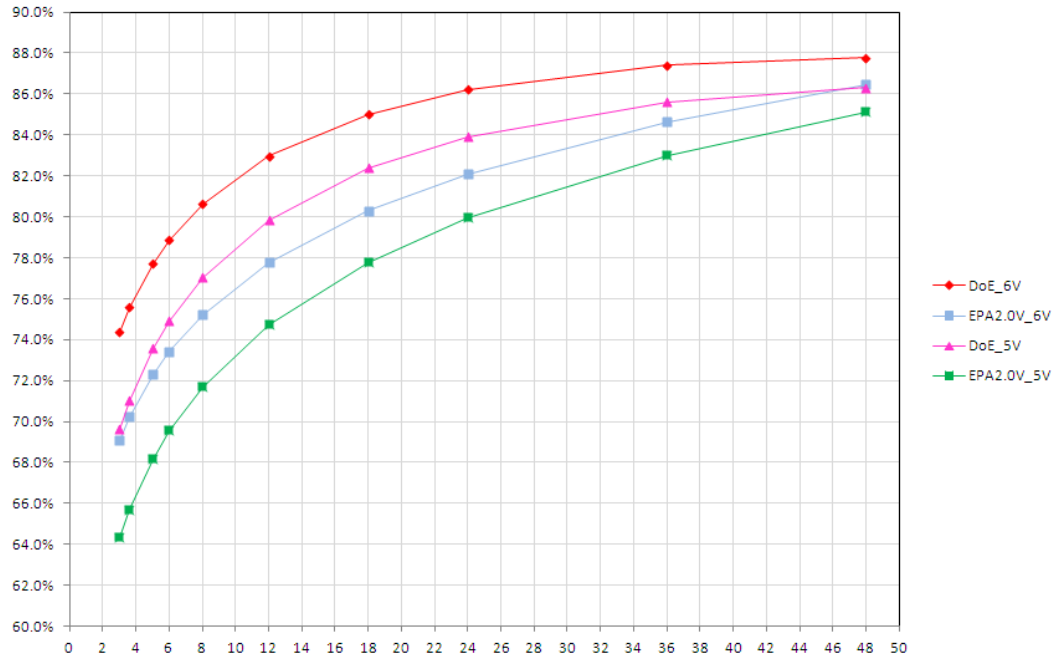
- Digital control technology optimizes green technology
- Design for Efficiency
 - iWatt technology achieves industry leading efficiency from “control” not from “component”
 - Achieve 80+ efficiency while reducing components
 - Advanced multi-mode operation
- EzEMI design
 - iWatt technology improves EMI performance from “control” not from “component”
 - Patented “dynamic gate control”
 - Advanced digital “EMI white noise generation”

ACDC, Low-Power, Low-voltage 5V (<15W)	
iW1676	BJT Drive, No ASU, 30mW, SOT23-5
iW1677	BJT, ASU, < 20mW, SOT-23-6
iW1700	BJT, ASU, < 10mW, Zero-Power, SOT23-6
iW1812	Integrate 800V Switch, 30mW, SOIC7
ACDC, Low-Power, Hi-Voltage 12V (<15W)	
iW1706	BJT Drive, No ASU, 50mW, SOT-23-5
iW1707	BJT Drive, <30mW, SOT-23-6
iW1677	BJT, ASU, < 20mW, SOT-23-6
iW1816	Integrate 800V Switch, 30mW, SOIC7
ACDC, Hi-Power, Low-voltage 5V (<20W)	
iW1699	FET, ASU, 30mW, CDC programmable, SOIC8
iW1762	FET, ASU, 10mW, CDC programmable, SOIC8
ACDC, Hi-Power, Hi-voltage 12V (<60W)	
iW1760	FET, ASU, 30mW, CDC programmable, SOIC8
iW1761	FET, ASU, 20mW, CDC programmable, SOIC8

AC-DC, Basic-Voltage External Power Supply		
Nameplate Output Power (P _{out})	Minimum Average Efficiency in Active Mode (expressed as a decimal)	Maximum Power in No-Load Mode [W]
0 to ≤ 1 watt	≥ 0.5 * P _{out} + 0.16	≤ 0.100
> 1 to ≤ 49 watts	≥ 0.071 * ln(P _{out}) - 0.0014 * P _{out} + 0.67	≤ 0.100
> 49 watts to ≤ 250 watts	≥ 0.880	≤ 0.210
> 250 watts	0.875	≤ 0.500
AC-DC, Low-Voltage External Power Supply		
Nameplate Output Power (P _{out})	Minimum Average Efficiency in Active Mode (expressed as a decimal)	Maximum Power in No-Load Mode [W]
0 to ≤ 1 watt	≥ 0.517 * P _{out} + 0.087	≤ 0.100
> 1 to ≤ 49 watts	≥ 0.0834 * ln(P _{out}) - 0.0014 * P _{out} + 0.609	≤ 0.100
> 49 watts to ≤ 250 watts	≥ 0.870	≤ 0.210
> 250 watts	0.875	≤ 0.500

SUMMARY: The Energy Policy and Conservation Act (EPCA) prescribes energy conservation standards for various consumer products and commercial and industrial equipment, including

Efficiency Requirement (EPA2.0 vs. DoE)



Vout (V)	Pout (W)	IC Recommendation
≤5	3~5W	iW1676/1677
	5W~10W	iW1706/iW1677/iW1699
	10W~20W	iW1699
>5	3~5W	iW1676/1677/iW1707/iW1706
	5W~10W	iW1677/iW1707
	10W~20W	iW1760

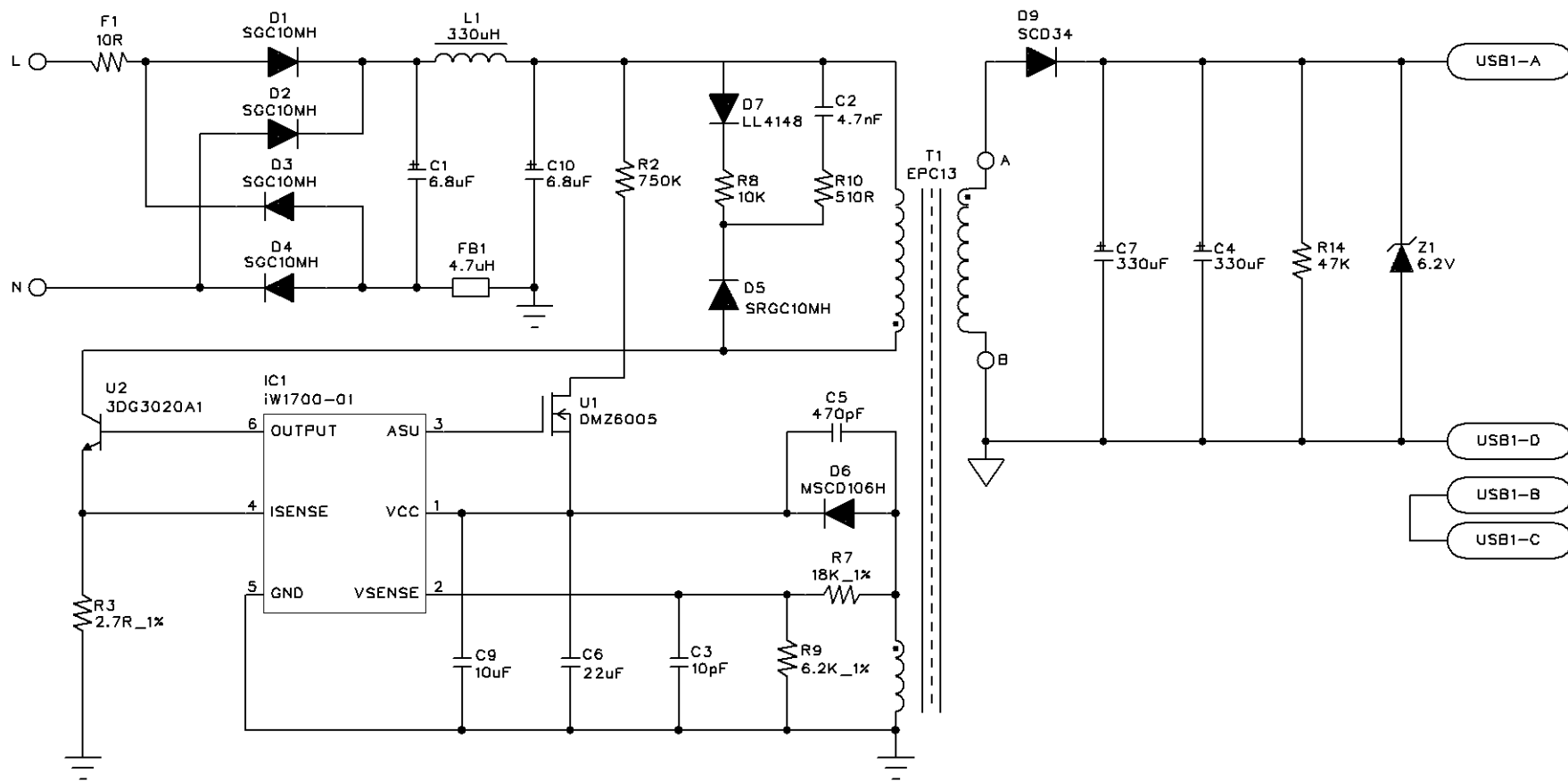
iWatt 12V1A High Efficiency Design Sample

V _{IN} (VAC)	P _{IN} (W)	V _{OUT} (V)	I _{OUT} (A)	V _{RIPPLE} (mV _{P-P})	P _{OUT} (W)	η (%)	OCP (A)	Average η (%)	EPA2.0 η(%)
90	0.018	12.02	0.000	16.0			1.19	87.6	74.74
	3.41	11.98	0.250	38.0	3.00	87.83			
	6.81	11.99	0.500	48.0	6.00	88.03			
	10.28	11.99	0.750	80.0	8.99	87.48			
	13.77	12.00	1.000	94.0	12.00	87.15			
115	0.021	12.02	0.000	14.0			1.18	88.4	
	3.39	11.99	0.250	54.0	3.00	88.42			
	6.76	12.00	0.500	52.0	6.00	88.76			
	10.17	12.00	0.750	78.0	9.00	88.50			
	13.64	12.00	1.000	80.0	12.00	87.98			
230	0.027	12.02	0.000	22.0			1.15	88.5	
	3.42	12.00	0.250	44.0	3.00	87.72			
	6.78	12.00	0.500	58.0	6.00	88.50			
	10.13	12.00	0.750	78.0	9.00	88.85			
	13.50	12.00	1.000	88.0	12.00	88.89			
264	0.036	12.03	0.000	16.0			1.13	88.0	
	3.45	11.99	0.250	56.0	3.00	86.88			
	6.83	11.99	0.500	76.0	6.00	87.77			
	10.14	11.97	0.750	78.0	8.98	88.54			
	13.55	12.01	1.000	94.0	12.01	88.63			

* Note: Output voltage is measured at end of PCB

Zero-Power SOLUTION: iW1700-01 For 5V1A Mini-TA Charge Design

Schematic



Circuit Board Photograph

3DG3020A1, TO-92

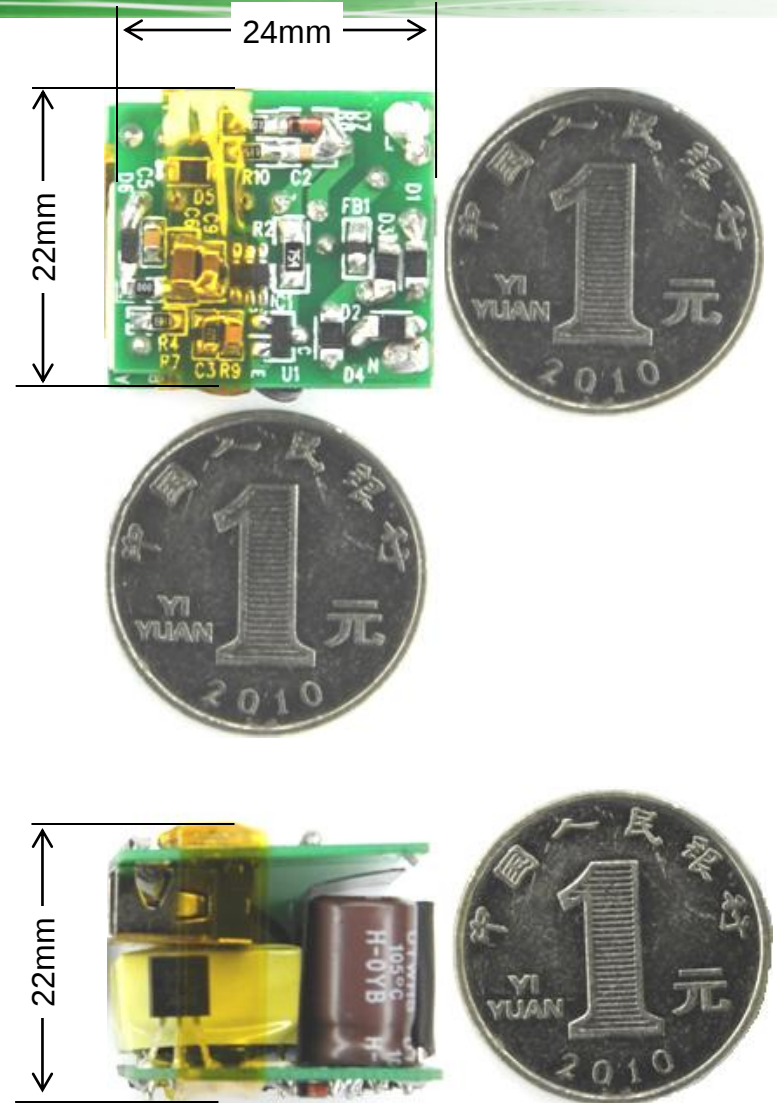
EPC13

PRIMARY BOARD

SECONDARY BOARD

iW1700-01

(300mV Cable-Drop-Compensation)



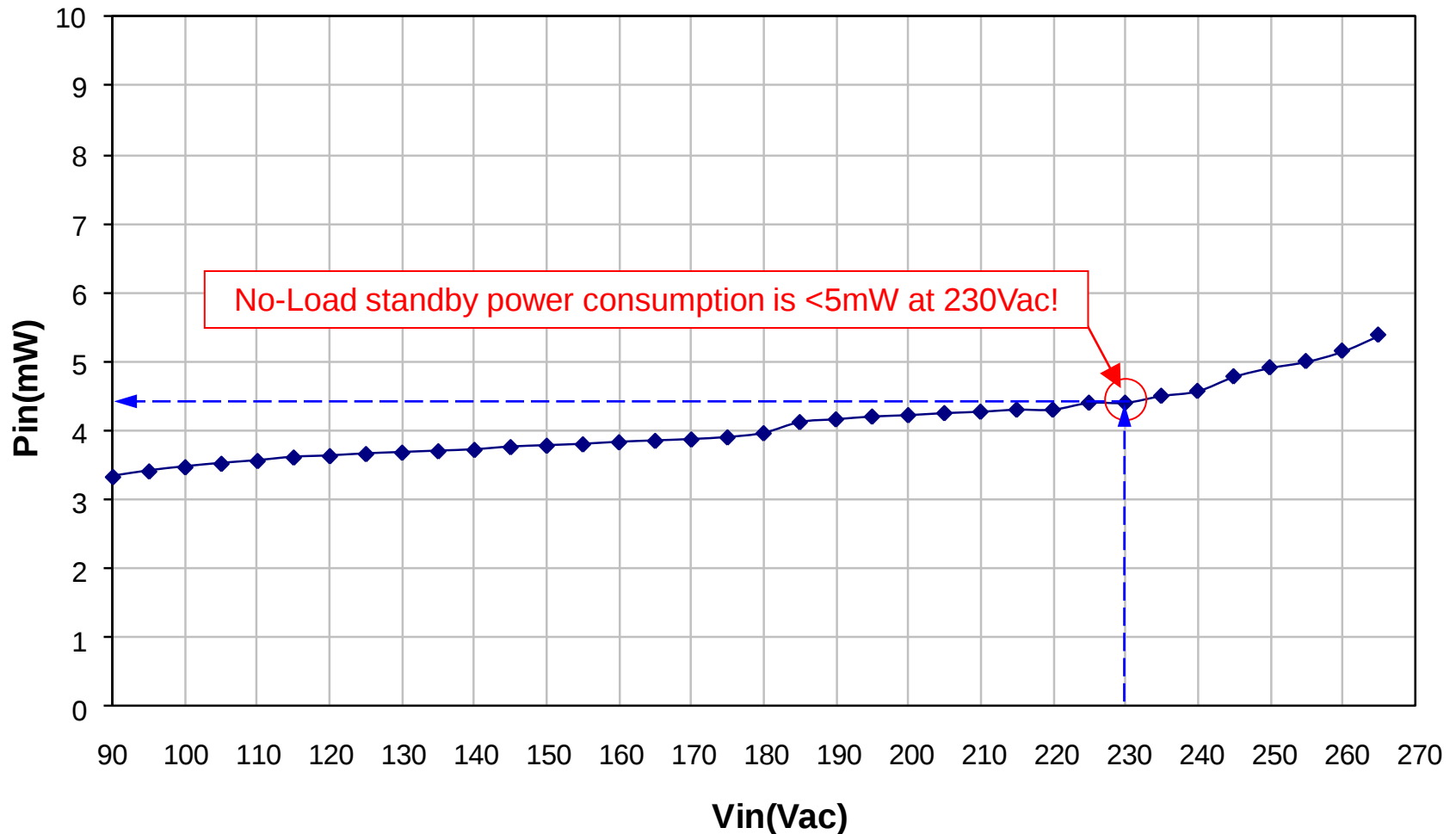
Regulation, Ripple and Efficiency Measurement

V _{IN} (V _{AC})	P _{IN} (W)	V _{OUT} (V)	I _{OUT} (mA)	V _{RIPPLE} (mV _{P-P})	P _{OUT} (W)	η (%)	OCP (A)	Average η(%)
90	0.0032	4.92	0	5.6			1.08	77.68
	1.59	5.03	250	29.2	1.26	79.17		
	3.24	5.09	500	37.6	2.55	78.65		
	5.08	5.23	750	53.6	3.92	77.14		
	7.02	5.32	1000	73.2	5.32	75.78		
115	0.0035	4.93	0	4.4			1.07	79.12
	1.58	5.03	250	32.8	1.26	79.55		
	3.20	5.10	500	39.6	2.55	79.69		
	4.95	5.21	750	44.4	3.91	79.05		
	6.81	5.32	1000	61.6	5.32	78.18		
230	0.0045	4.92	0	6.4			1.07	79.12
	1.62	5.05	250	38.0	1.26	78.24		
	3.23	5.09	500	44.8	2.55	78.91		
	4.93	5.23	750	52.4	3.92	79.57		
	6.67	5.32	1000	59.2	5.32	79.75		
264	0.0054	4.92	0	4.4			1.05	78.43
	1.64	5.05	250	42.4	1.26	77.22		
	3.26	5.10	500	47.6	2.55	78.17		
	4.95	5.22	750	54.2	3.91	78.98		
	6.71	5.32	1000	64.4	5.32	79.35		

* Note: Output voltage is measured at end of PCB

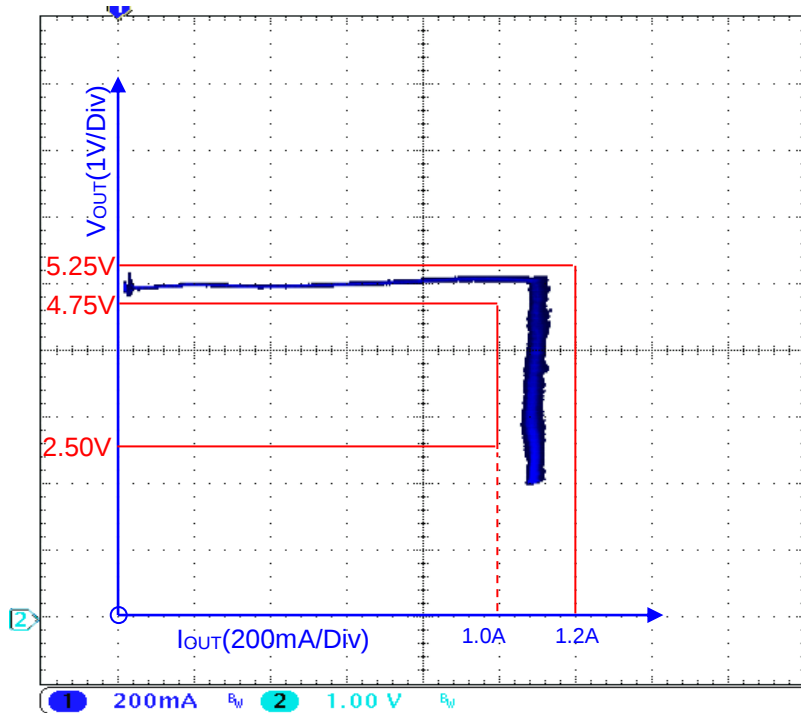
No-Load Standby Power Consumption

No-Load Standby Power Consumption

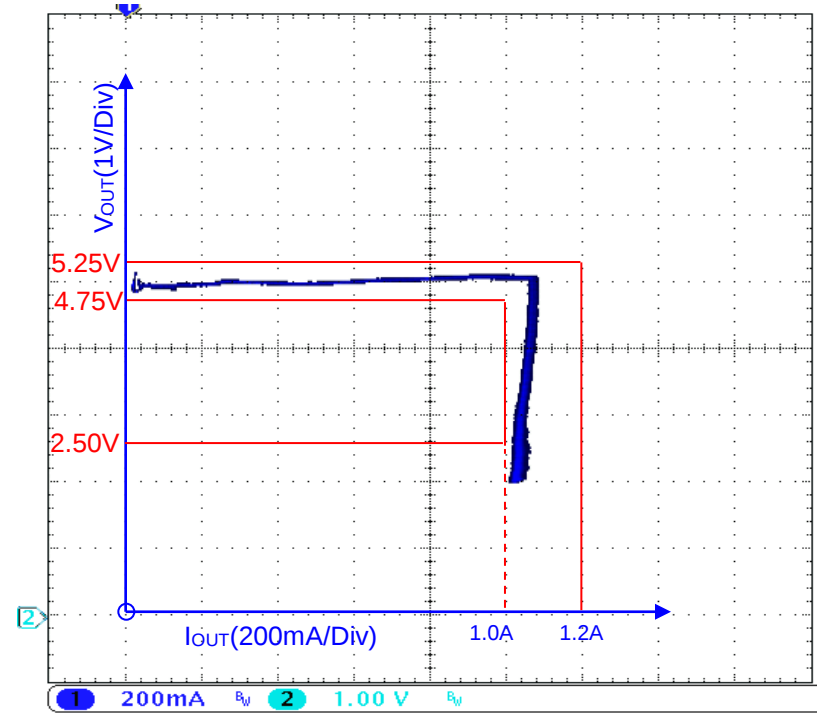


Output VI Characteristics

$V_{IN}=90V_{ac}/50Hz$



$V_{IN}=264V_{ac}/50Hz$



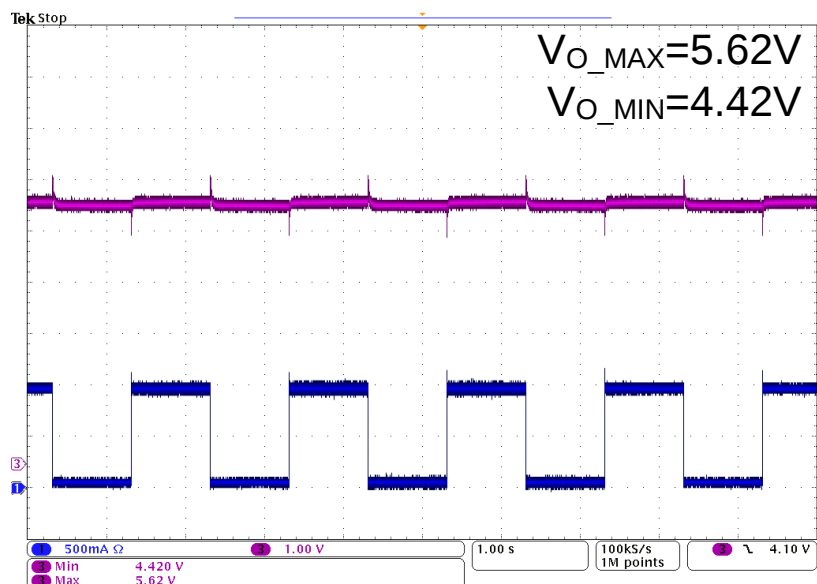
* Note: Output voltage is monitored at end of Output DC-Cable (26AWG1.2m, $R_{CABLE}=0.34\Omega$).

Dynamic Load Response

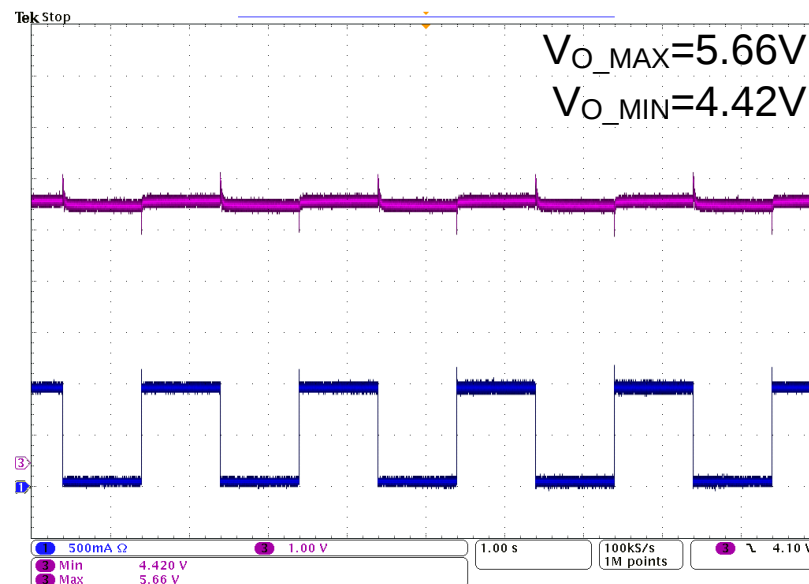
Test Conditions:

- 1). Load: *0mA-1000mA-0A*
- 2). Frequency: *1Hz*
- 3). Duty-Cycle: *50%*
- 4). Slew-Rate: *0.1A/us*
- 5). V_{OUT} is monitored at end of Cable(26AWG/1.2M, $R_{CABLE}=0.34\Omega$)

$V_{in}=90Vac$



$V_{in}=264Vac$



CH2: Output Voltage, 1V/Div; CH1: Output Current, 0.5A/Div

iW1812-20 for 3W Soymilk machine Design

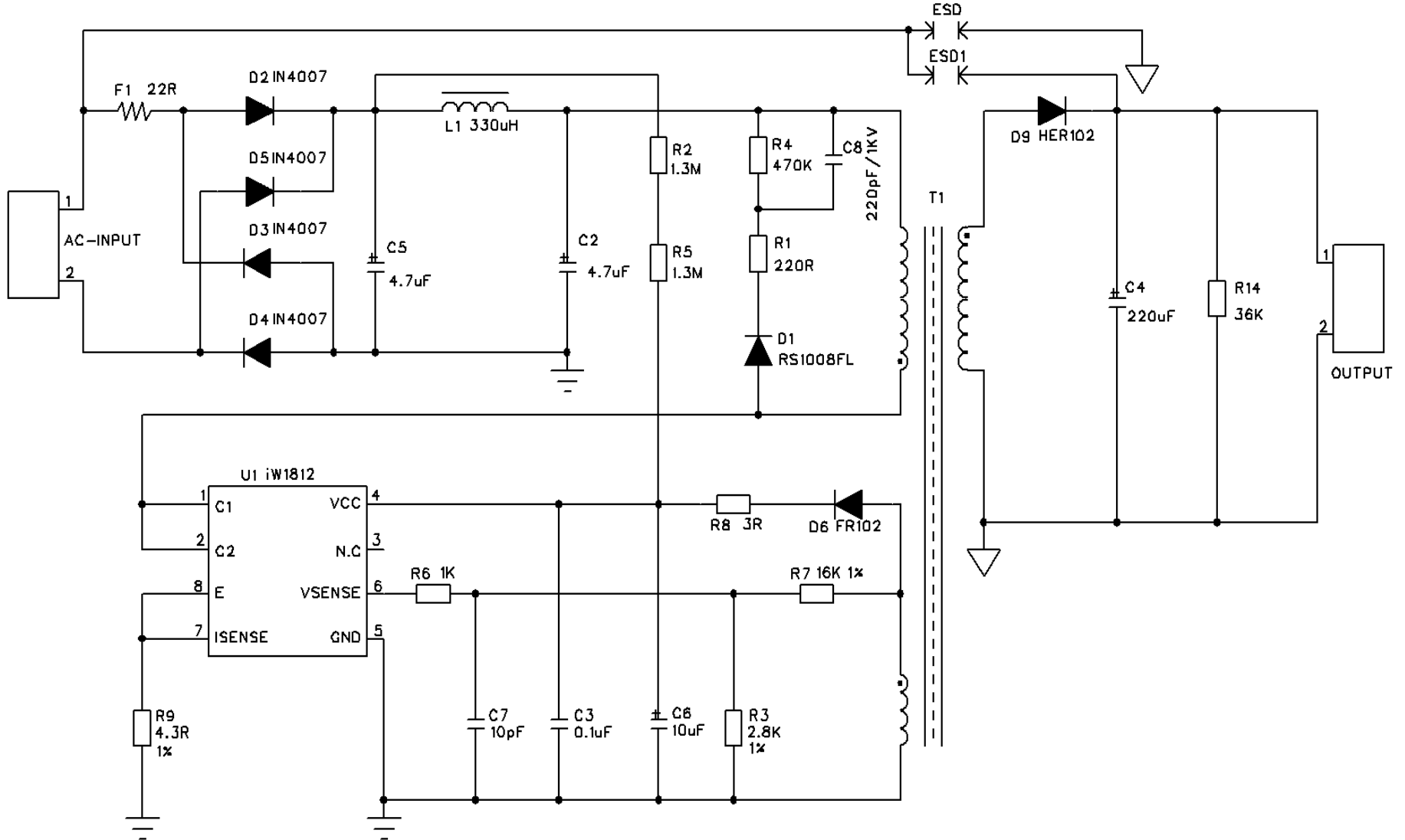
General Design Specification :

1. AC Input Range 90-264Vac
2. DC Output 12V0.2A
3. Meet “**100mW**” No-Load Standby Power Consumption Requirement
4. No Y-CAP Design

1. Specification

Description	Symbol	Min	Typ	Max	Units	Comment
Input						
Voltage	V_{IN}	90		264	V _{AC}	2 Wire
Frequency	f_{LINE}	63	50/60	47	Hz	
No-load Input Power (230V _{AC})				100	mW	
Output						
Output Voltage	V_{OUT}	11.4		12.6	V	Measured at the end of PCB
Output Current	I_{OUT}	0		0.2	A	
Output Ripple Voltage	V_{RIPPLE}			150	mV _{P-P}	Measured at the end of PCB $I_{OUT}=0.2A$ @ $T_A = 25\text{ }^{\circ}\text{C}$ 20 MHz Bandwidth
Total Output Power						
Continuous Output Power	P_{OUT}		2.4		W	
Over Current Protection	OCP			0.35	A	Auto-restart
Active Mode Efficiency (Meet EPA2.0 Requirement)	η	67.7			%	Measured at end of PCB, $V_{IN} = 115V_{AC}$ and 230VAC ($T_{AMB} = 25\text{ }^{\circ}\text{C}$).
Environmental						
Conducted EMI		Meets CISPR22B / EN55022B				
Safety		Designed to meet IEC950, UL1950 Class II				
Ambient Temperature	T_{AMB}	0		40	$^{\circ}\text{C}$	Free convection, sea level

2. Schematic

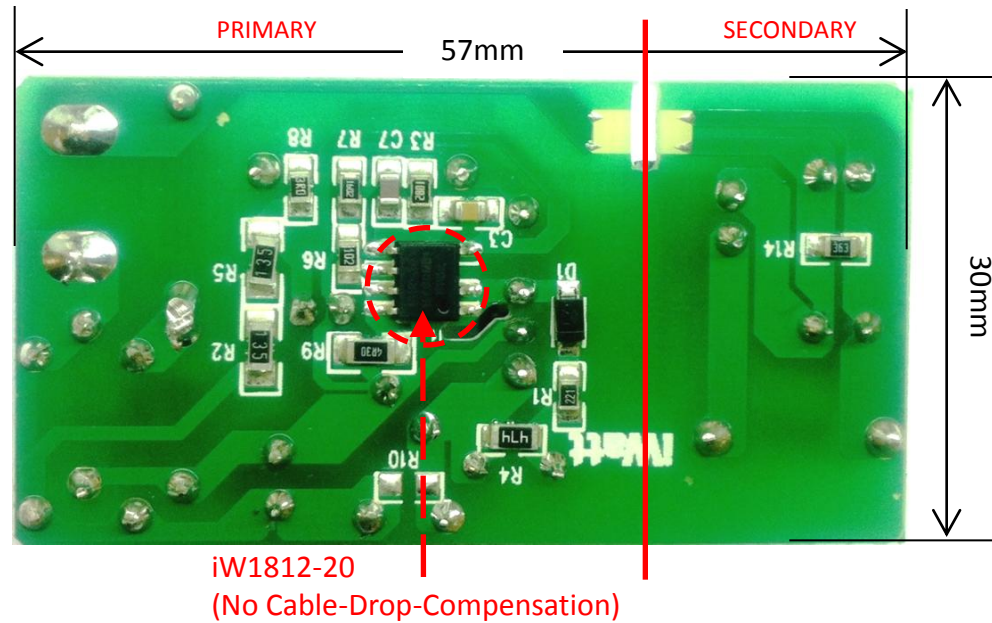


3. Circuit Board Photograph

Top side



Bottom side

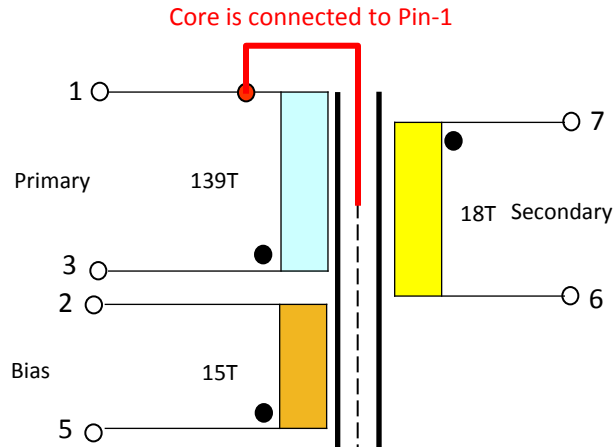


4. Bill of Material

Item	Qty.	Ref.	Description
1	1	U1	iW1812-20, Off-line Digital PSR & VMS PWM Controller, SOIC-7
2	2	C2,C5	4.7uF, 400V, E-Cap, Φ 8mmX12mm
3	1	C3	0.1uF, 50V, X7R, SMD-0805
4	1	C4	220uF, 25V, Low ESR E-Cap, Φ 8mmX12mm
5	1	C6	10uF, 50V, Low ESR E-Cap, Φ 5mmX11.5mm
6	1	C7	10pF, 25V, X7R, SMD-0805
7	1	C8	220pF, 1kV, Ceramic Capacitor
8	1	D1	RS1008FL, 1A 800V, Fast Rectifier Diode, SOD-123FL
9	4	D2,D3,D4,D5	1N4007, 1A1000V, Rectifier Diode, DO-41
10	1	D6	FR102, 1A100V, Fast Recovery Rectifier (Trr=150ns), DO-41
11	1	D9	HER102, 1A100V, Ultra Fast Diode, DO-41
12	1	L1	330uH, Color Ring Inductor, 0410
13	1	R1	220 Ω ±5%, SMD-0805
14	2	R2,R5	1.3M Ω ±5%, SMD-1206
15	1	R3	2.8K Ω ±1%, SMD-0805
16	1	R4	470K Ω ±5%, SMD-1206
17	1	R6	1K Ω ±5%, SMD-0805
18	1	R7	16K Ω ±1%, SMD-0805
20	1	R8	3 Ω ±5%, SMD-0805
19	1	R9	4.3 Ω ±1%, SMD-1206
21	1	R14	36K Ω ±5%, SMD-0805
22	1	F1	22 Ω , Fusible Resistor, 1Ws
23	1	T1	EE13, vertical Taye
24	1	AC-INPUT	Connector, 3PIN2, L=3.96mm
25	1	OUTPUT	Connector, 2PIN, L=2.54mm
26	1	PCB	Single Side Board, 94V0

5. Transformer Design

SCHEMATIC



ELECTRICAL SPECIFICATIONS:

1. Primary Inductance (L_p) = $3.15\text{mH} \pm 7\%$ @10KHz
2. Primary Leakage Inductance
3. Electrical Strength = 3KV, 50/60Hz, 1Min

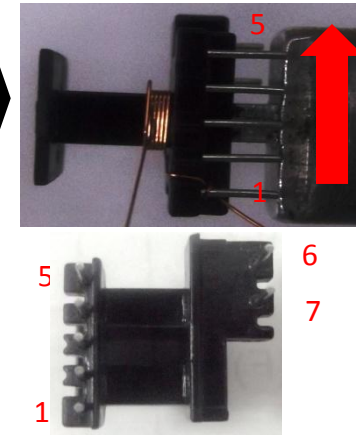
MATERIALS:

1. Core : EE13 (Ferrite Material TDK PC40 or equivalent)
2. Bobbin : EE13 Vertical.
3. Magnet Wires (Pri) : Type 2-UEW
4. Magnet Wire (Sec) : Triple Insulated Wires
5. Layer Insulation Tape: 3M1298 or equivalent.

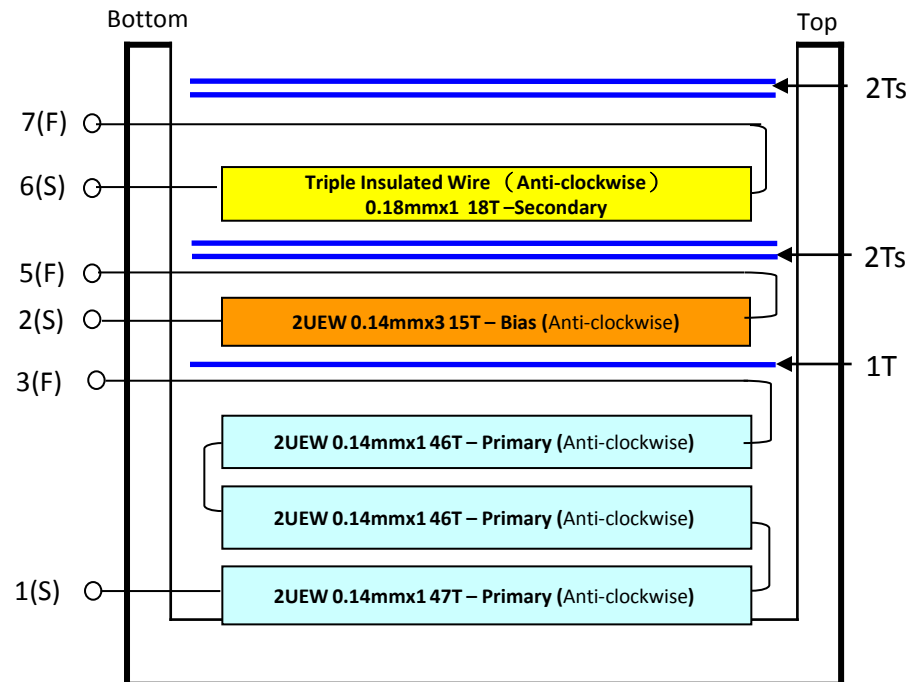
FINISHED :

1. Varnish the complete assembly

Winding Start pin1 & End pin-3 in "Clockwise" direction – looking from Pin 1/5 side of the Bobbin.



Rotating direction of winding machine

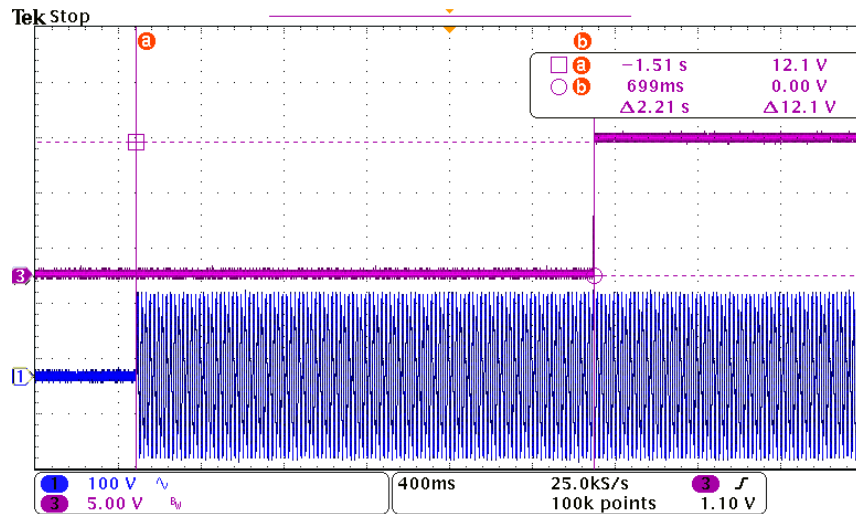


6. Regulation, Ripple and Efficiency Measurement

* Note: Output voltage measured at end of PCB

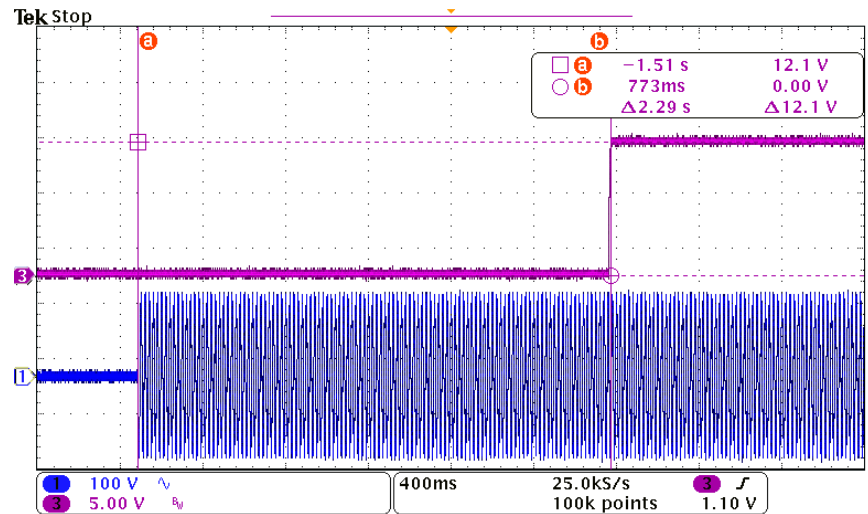
V_{IN} (V _{AC})	P_{IN} (W)	V_{OUT} (V)	I_{OUT} (mA)	V_{RIPPLE} (mV _{P-P})	P_{OUT} (W)	η (%)	OCP (mA)	Average η (%)
85	0.028	11.96	0	44.0			300	75.83
	0.787	11.89	50	39.2	0.59	75.54		
	1.546	11.91	100	53.6	1.19	77.01		
	2.349	11.91	150	67.6	1.79	76.05		
	3.189	11.92	200	80.8	2.38	74.74		
115	0.031	11.94	0	48.0			310	77.58
	0.781	11.89	50	45.6	0.59	76.12		
	1.521	11.91	100	57.6	1.19	78.27		
	2.287	11.91	150	56.8	1.79	78.12		
	3.063	11.92	200	67.2	2.38	77.81		
230	0.061	11.94	0	52.0			310	75.35
	0.838	11.89	50	54.4	0.59	70.94		
	1.576	11.91	100	50.8	1.19	75.54		
	2.322	11.91	150	64.8	1.79	76.95		
	3.056	11.91	200	67.2	2.38	77.96		
264	0.075	11.94	0	58.0			310	73.66
	0.867	11.89	50	48.4	0.59	68.57		
	1.613	11.91	100	57.2	1.19	73.81		
	2.366	11.91	150	69.2	1.79	75.52		
	3.105	11.91	200	64.8	2.38	76.73		

7. Turn On Delay Time



100V_{AC}, No Load

T_{ST_DELAY}=2.21S

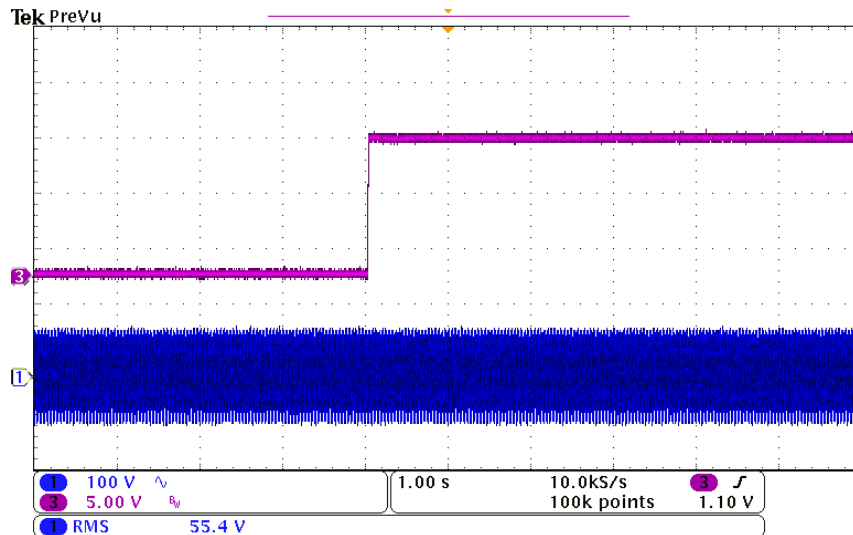


100V_{AC}, Full Load

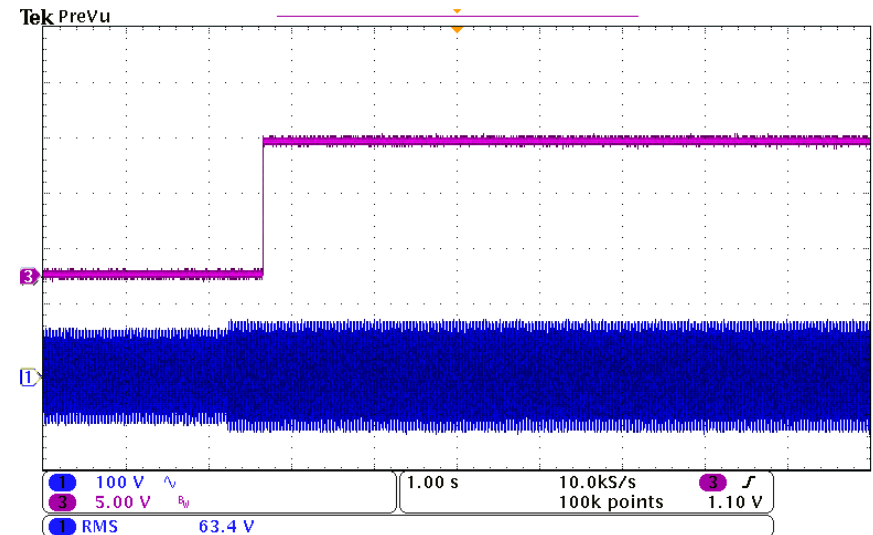
T_{ST_DELAY}=2.29S

8. AC Startup Voltage Characteristic

No Load, $V_{IN_STARTUP} = 55.4V_{AC}$

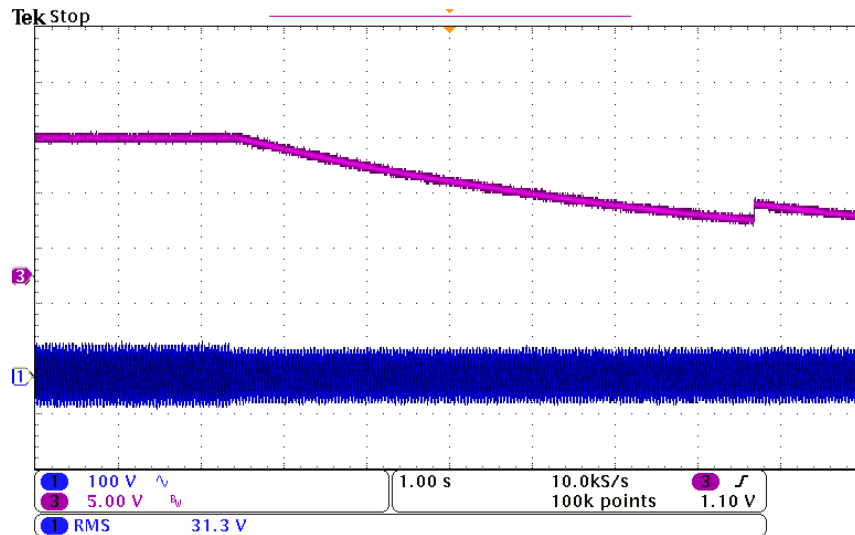


Full Load, $V_{IN_STARTUP} = 63.4V_{AC}$

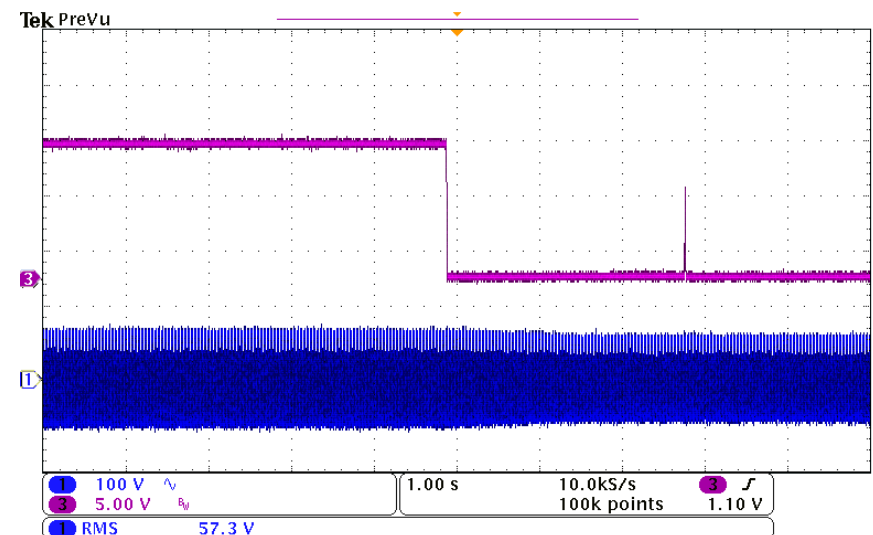


9. AC Brownout Voltage Characteristic

No Load, $V_{IN_BROWNOUT} = 31.3V_{AC}$

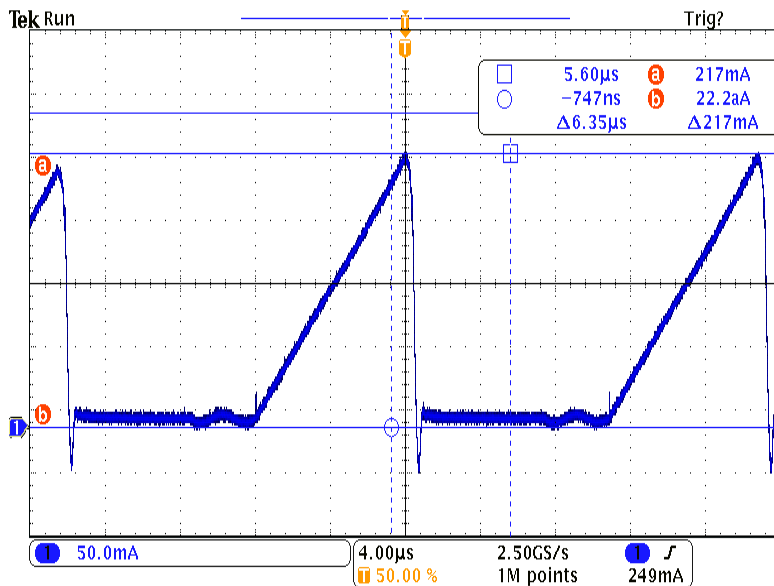


Full Load, $V_{IN_BROWNOUT} = 57.3V_{AC}$



10. Transformer Flux Density

($N_p = 139$ Ts, $L_p = 3.3$ mH, $A_e = 17.1 \text{ mm}^2$ EE13)



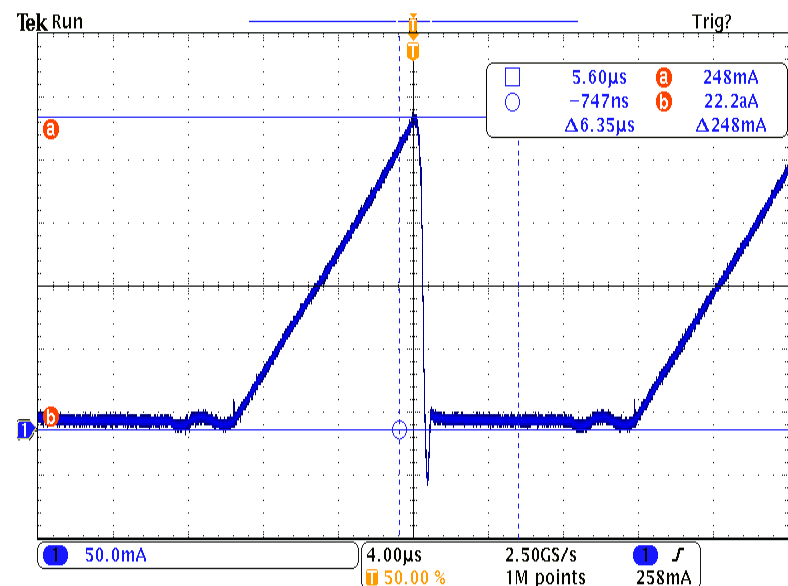
I_{PRI} is monitored at 85Vac and 200mA load

$I_{PRI} = 217 \text{ mA}$

$$B_{MAX} = (I_{PRI} * L_p) / (N_p * A_E)$$

$$= (217 * 3.3) / (139 * 17.1)$$

$$= 0.301 \text{ Tesla}$$



I_p is monitored at 85Vac and 300mA load (Max Output Power).

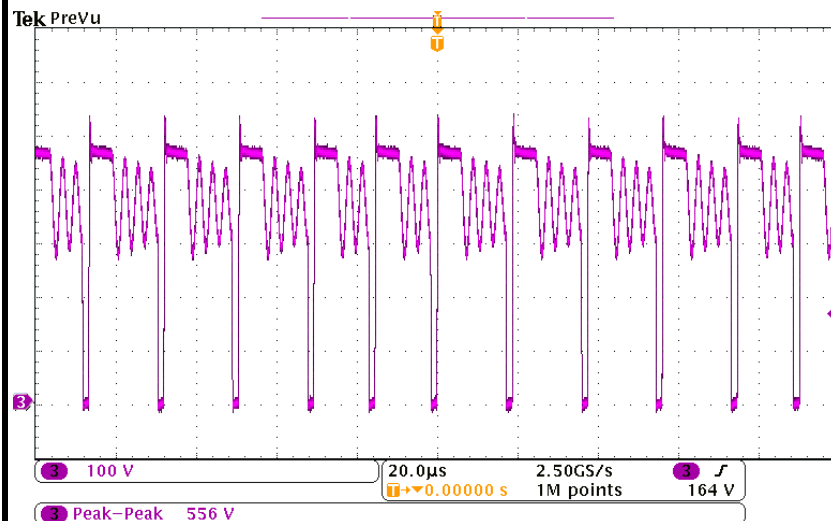
$I_{PRI} = 248 \text{ mA}$

$$B_{MAX} = (I_{PRI} * L_p) / (N_p * A_E)$$

$$= (248 * 3.3) / (139 * 17.1)$$

$$= 0.344 \text{ Tesla}$$

11. V_{CE} Waveform



Test Condition:

$V_{IN}=264V_{AC}$, $I_{OUT_CV}=200mA$

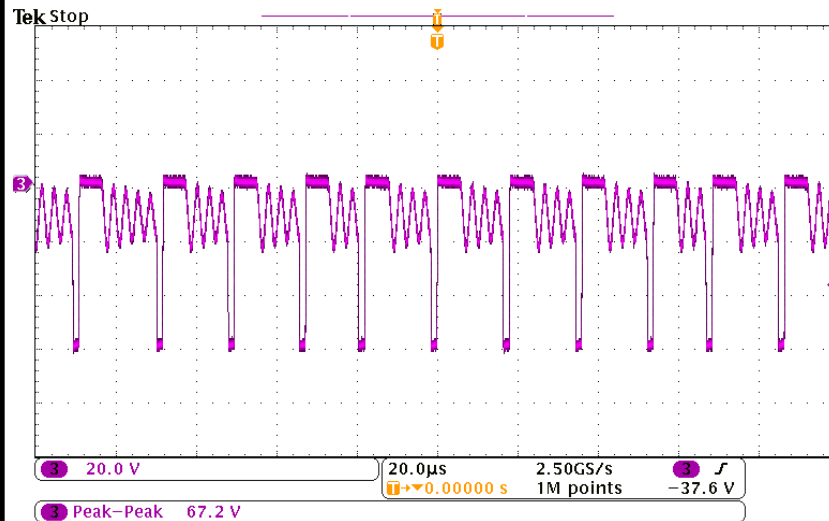
Result:

$V_{CE_MAX}=556V$

iW1812-20

Parameter Note		Symbol	Rating	Unit
Collector-Base Breakdown Voltage		V_{CBO}	800	V
Collector-Emitter Breakdown Voltage		V_{CEO}	450	V
Emitter-Base Breakdown Voltage		V_{EBO}	9	V
Collector Current		I_C	1.5	A
Power Dissipation	$T_a=25^{\circ}C$	P_{tot}	0.8	W
Junction Temperature		T_j	150	$^{\circ}C$
Storage Temperature		T_{stg}	$-55 \sim 150$	$^{\circ}C$

12. Output Diode



Test Condition:

$V_{IN}=264V_{AC}$, $I_{OUT_CV}=200mA$

Result:

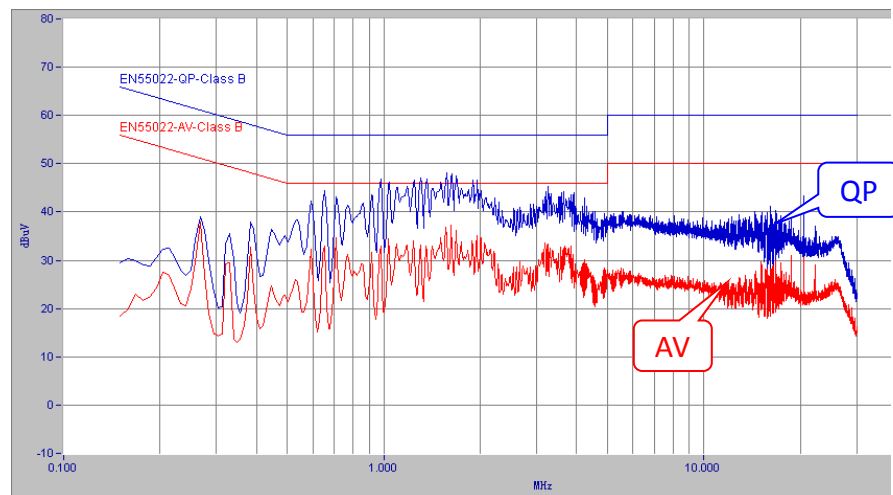
$V_{D9_PP}=67.2V$

Appendix – Simple Specification for used Transistor(HER102)

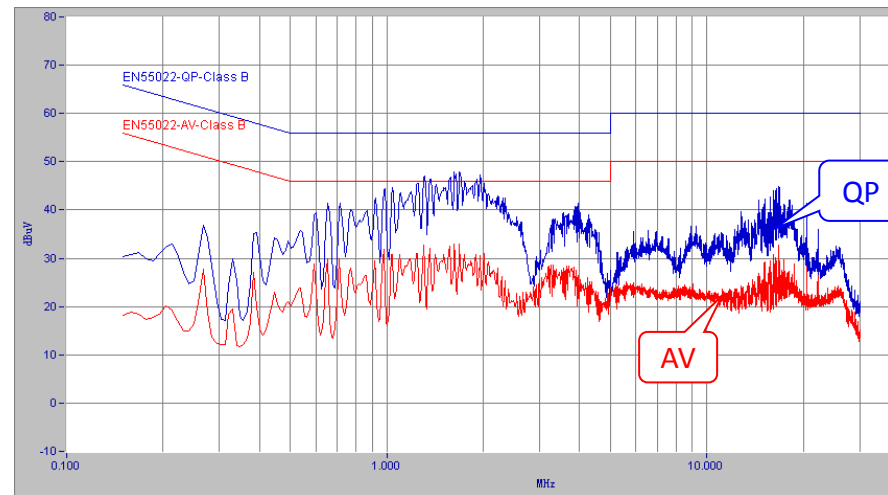
Type Number	HER 101	HER 102	HER 103	HER 104	HER 105	HER 106	HER 107	HER 108	Units
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T _A = 55°C	1.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	30								A
Maximum Instantaneous Forward Voltage @ 1.0A	1.0				1.3	1.7			V
Maximum DC Reverse Current @ T _A =25°C at Rated DC Blocking Voltage @ T _A =100°C	5.0 100								uA uA
Maximum Reverse Recovery Time (Note 1)	50					75			nS
Typical Junction Capacitance (Note 2)	20					15			pF

13. Conducted EMI

$V_{IN}=230V_{ac}/50Hz$, Live



$V_{IN}=230V_{ac}/50Hz$, Neutral



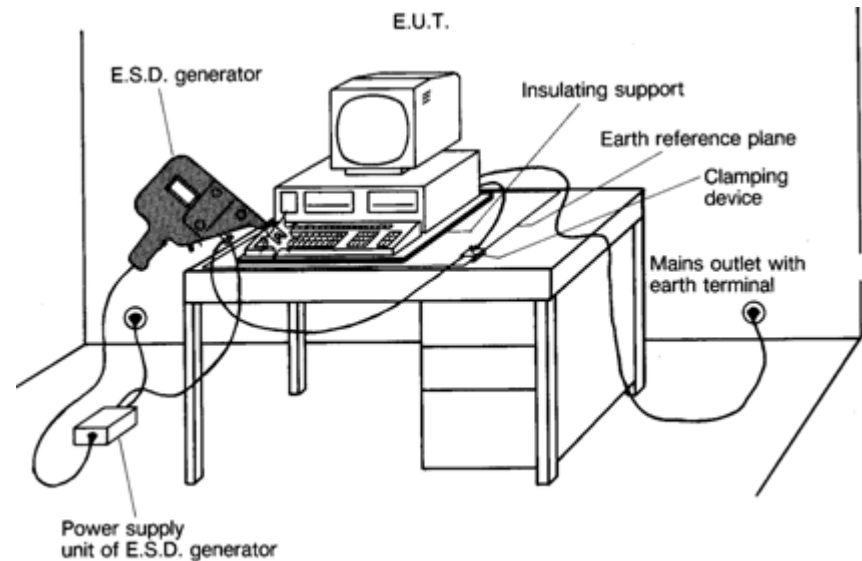
Note: Resistive & Full load; output (-) is Grounding.

14. ESD (IEC 61000-4-2)

Test condition:

$V_{IN}=230VAC/50Hz$, No_Load and Full_Load (Resistive Load)

Air-Discharged		Result (no-load)	Result (full-load)
15KV	+	PASS	PASS
	-	PASS	PASS
18KV	+	PASS	PASS
	-	PASS	PASS
20KV	+	PASS	PASS
	-	PASS	PASS
22KV	+	PASS	PASS
	-	PASS	PASS
23KV	+	PASS	PASS
	-	PASS	PASS
25KV	+	PASS	PASS
	-	PASS	PASS



iW1812 for 5W Microwave oven Design

General Design Specification:

- 1.AC Input Range: 90-264Vac
- 2.DC Output: 5.0V/250mA,12V/250mA
- 3.Meet “**100mW**” No-Load standby Power Consumption Requirement
- 4.Max Ripple <150mV_{P-P}

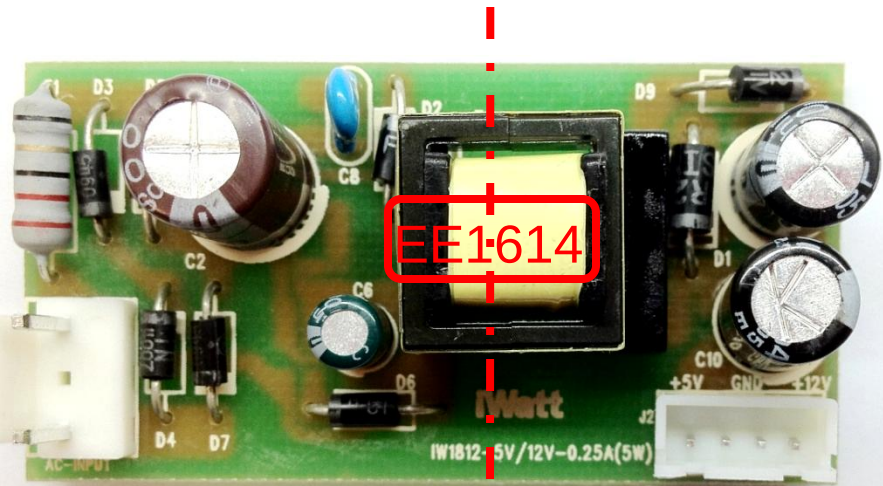
1. Specification

Description	Symbol	Min	Typ	Max	Units	Comment
Input						
Voltage	V _{IN}	90		264	V _{AC}	2 Wire
Frequency	f _{LINE}	47	50/60	63	Hz	
No-load Input Power (230V _{AC})				100	mW	
Output						
Output Voltage	V _{OUT1}	11	12	14	V	Measured at the end of PCB
	V _{OUT2}	4.8	5.0	5.3		
Output Current	I _{OUT1} /I _{OUT2}	0		0.25	A	
Output Ripple Voltage	V _{RIPPLE}			150	mV _{P-P}	Measured at the end of PCB I _{OUT1} =0.25A, I _{OUT2} =0.25A@T _A = 25 °C 20 MHz Bandwidth
Total Output Power						
Continuous Output Power	P _{OUT}		4.25		W	
Over Current Protection	OCP			0.35	A	Auto-restart
Active Mode Efficiency (Meet EPA2.0 Requirement)	η	72			%	Measured at end of PCB, V _{IN} = 115VAC and 230VAC (T _{Amb} = 25 °C).
Environmental						
Conducted EMI		Meets CISPR22B / EN55022B				
Safety		Designed to meet IEC60065, IEC60950,UL1950 Class II				
Ambient Temperature	T _{AMB}	0		40	° C	Free convection, sea level



3. Circuit Board Photograph

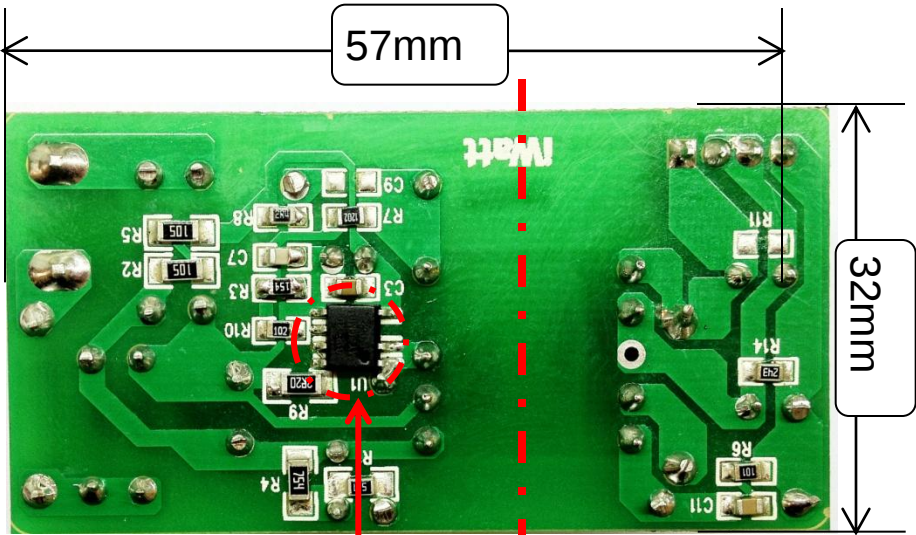
Top side



Primary

Secondary

Bottom side



Primary

Secondary

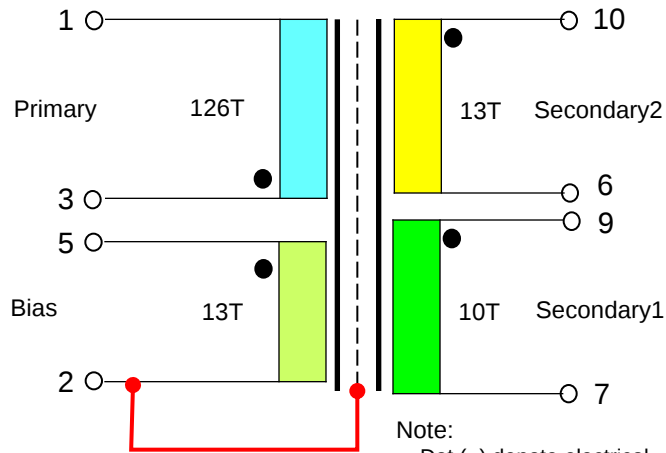
iW1812-20 PSR VMS Controller
(No Cable-Drop-Compensation)

4. Bill of Material

Item	Qty	Reference	Description
1	1	U1	iW1812, Off-line Digital & Primary VMS Controller, SOIC-7
2	1	C2	10uF/400V, E-Cap, 10*16
3	1	C3	0.1uF, X7R, SMD-0805
4	1	C4	470uF/16V, E-Cap, 8*12 Low ESR
5	1	C6	10uF/50V, E-Cap, 5*11 Low ESR
6	1	C7	22pF, NPO, SMD-0805
7	1	C8	470pF, 1KV, Ceramic Capacitor
8	1	C10	680uF/10V, E-Cap, 8*12 Low ESR
9	1	C11	100pF, 250V SMD-0805
10	1	D1	SR260, 2A 60V, Schottky Barrier Diode DO-15
11	1	D2	FR107, 1A 1000V, Fast Rectifier Diode DO-41
12	4	D3, D4, D5, D7	1N4007, 1A 1000V, Rectifier diode DO-41
13	1	D6	FR102, 1A 100V, Fast Recovery Rectifier (Trr=150ns), DO-41
14	1	D9	HER102, 1A 100V, Ultra Fast Recovery Rectifier DO-41
15	1	R1	510Ω ±5%, SMD-0805
16	2	R2, R5	1MΩ ±5%, SMD-1206
17	1	R3	3.5KΩ ±1%, SMD-0805
18	1	R4	750KΩ ±5%, SMD-1206
19	1	R6	100Ω ±5%, SMD-0805
20	1	R7	12KΩ ±1%, SMD-0805
21	1	R8	2.4Ω ±5%, SMD-0805
22	1	R9	2.2Ω ±1%, SMD-1206
23	1	R10	1KΩ ±5%, SMD-0805
24	1	R14	24KΩ ±5%, SMD-0805
25	1	F1	22Ω, Fusible Resistor, 1W
26	1	AC-INPUT	Connector, 3PIN2, L=3.96mm
27	1	OUTPUT	Connector, 4PIN, L=2.54mm
28	1	T1	EE1614, Horizontal
29	1	PCB	Single Side Board, T=1.0mm FR-1 94V0
30	NC	L1	CM Inductor >25mH 0.16*80Ts
31	NC	L2	330uH, Color Ring Inductor, 0410
32	NC	C1	X-Cap 0.1uF/275V

5. Transformer Design

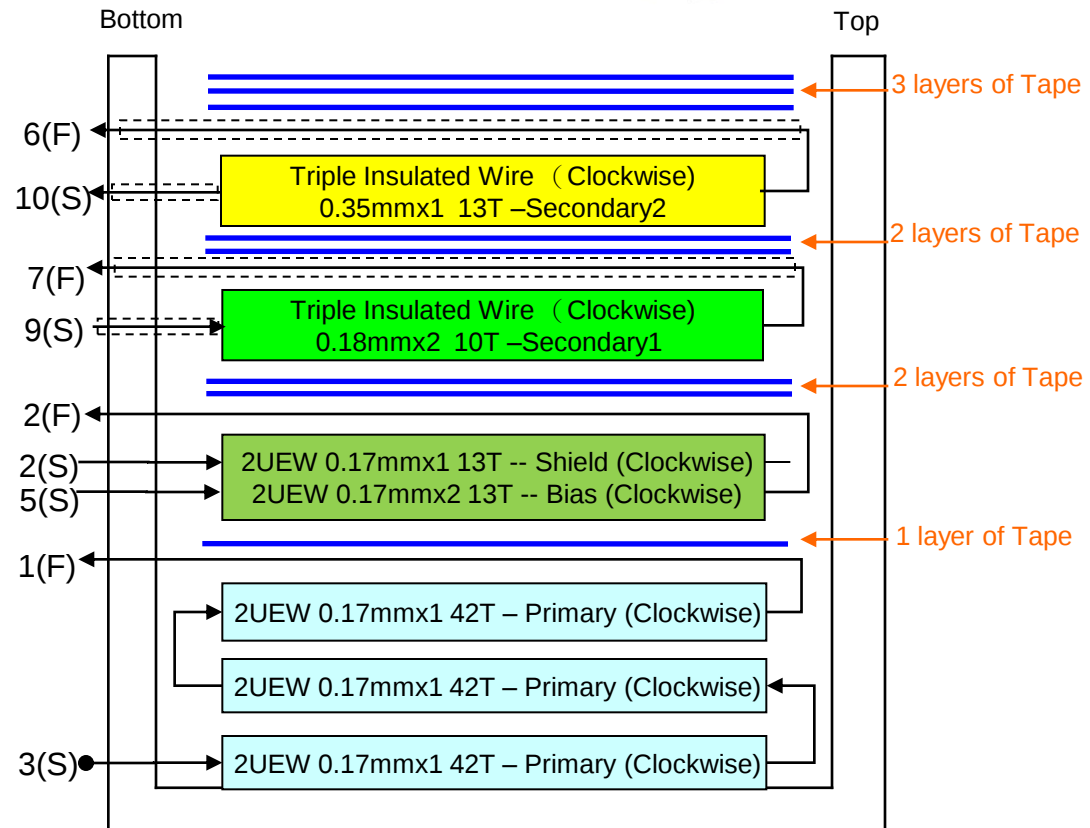
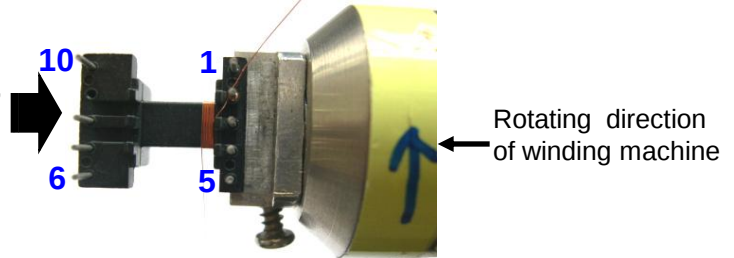
SCHEMATIC



Core is connected to Pin-2

Instruction for start of first winding...

Winding Start pin-3 & End pin-1 in "Clockwise" direction – looking from Pin side of the Bobbin.



ELECTRICAL SPECIFICATIONS:

1. Primary Inductance (L_p) = $1.50\text{mH} \pm 7\%$ @ 10KHz
2. Primary Leakage Inductance $< 5\% \times L_p$, Short pin6-pin10
3. Electrical Strength = 3KV, 50/60Hz, 1Min

MATERIALS:

1. Core : EE16 (Ferrite Material TDK PC40 or equivalent)
2. Bobbin : EE16 Vertical.
3. Magnet Wires (Pri) : Type 2-UEW
4. Magnet Wire (Sec) : Triple Insulated Wires
5. Layer Insulation Tape : 3M1298 or equivalent.

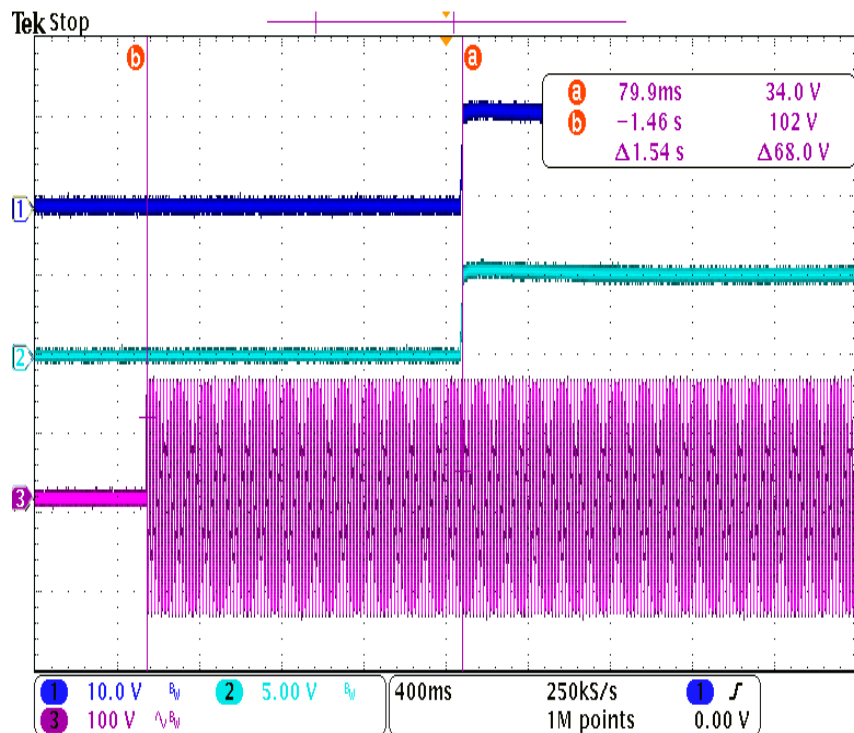
FINISHED :

1. Varnish the complete assembly

6. Regulation, Ripple and Efficiency Measurement

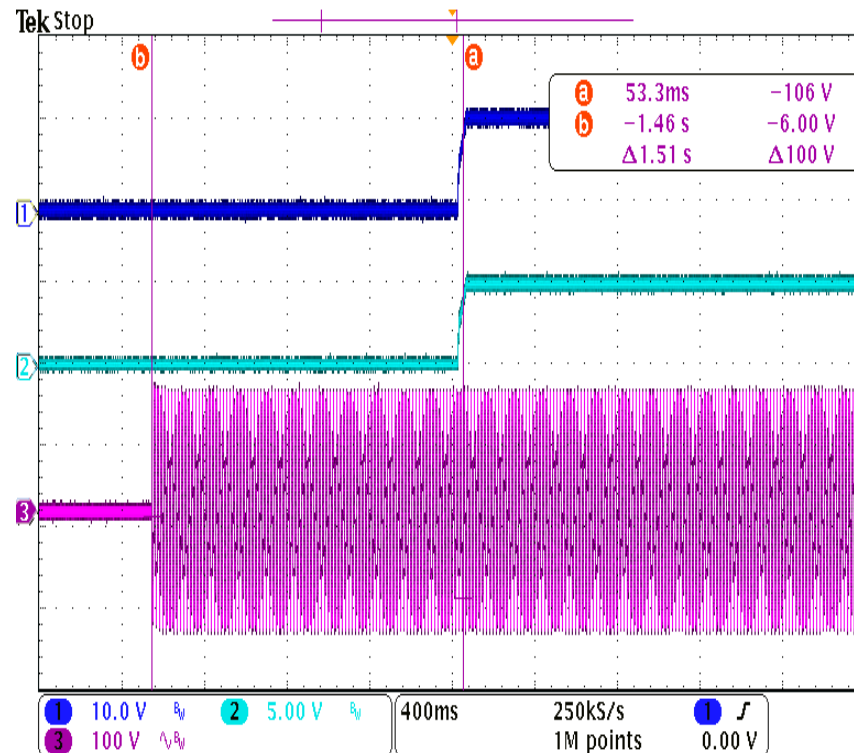
V_{IN} (V _{AC})	P_{IN} (W)	$V_{OUT(5V)}$ (V)	$V_{OUT(12V)}$ (V)	$I_{OUT(5V)}$ (mA)	$I_{OUT(12V)}$ (mA)	$V_{RIPPLE(5V)}$ (mV _{P-P})	$V_{RIPPLE(12V)}$ (mV _{P-P})	P_{OUT} (W)	η (%)
90	0.021	5.09	11.35	0	0				
	0.283	4.95	11.57	40	0			0.198	69.96
	1.620	4.95	12.27	250	0			1.238	76.44
	3.701	5.12	11.41	0	250			2.852	77.05
	5.335	4.98	11.31	250	250	57	92	4.073	76.34
115	0.026	5.08	11.34	0	0				
	0.292	4.95	11.56	40	0			0.198	67.81
	1.616	4.95	12.28	250	0			1.239	76.64
	3.655	5.11	11.41	0	250			2.851	78.01
	5.220	4.98	11.31	250	250	54	82	4.072	78.01
230	0.068	5.07	11.32	0	0				
	0.370	4.95	11.56	40	0			0.198	53.51
	1.688	4.95	12.36	250	0			1.239	73.37
	3.720	5.11	11.40	0	250			2.849	76.58
	5.232	4.98	11.30	250	250	48	80	4.070	77.79
264	0.088	5.07	11.31	0	0				
	0.401	4.95	11.58	40	0			0.198	49.42
	1.723	4.95	12.36	250	0			1.239	71.88
	3.766	5.10	11.39	0	250			2.848	75.62
	5.290	4.98	11.30	250	250	51	84	4.070	76.94

7. Turn On Delay Time



100V_{AC},CH1,CH2:No Load

T_{ST_DELAY}=1.54S



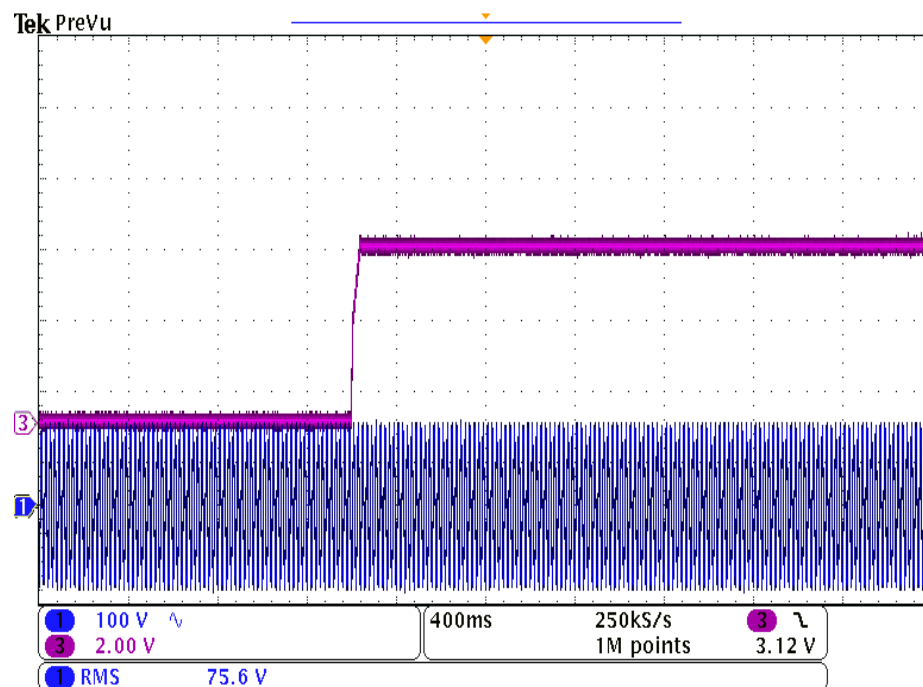
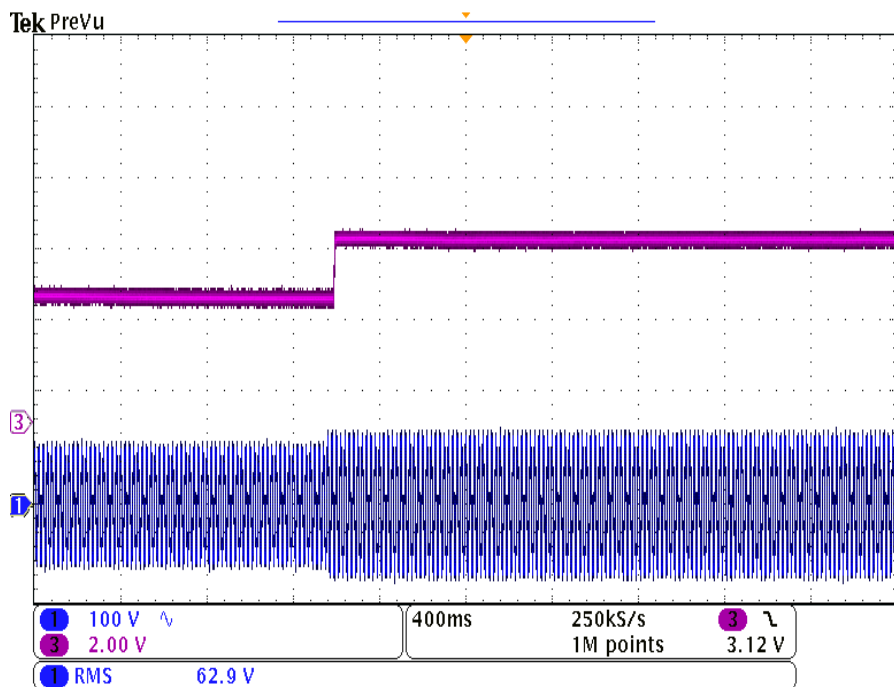
100V_{AC},CH1,CH2:Full Load

T_{ST_DELAY}=1.51S

CH1:12V CH2:5.0V CH3:AC INPUT

iWatt
Power Management Simplified Digitally

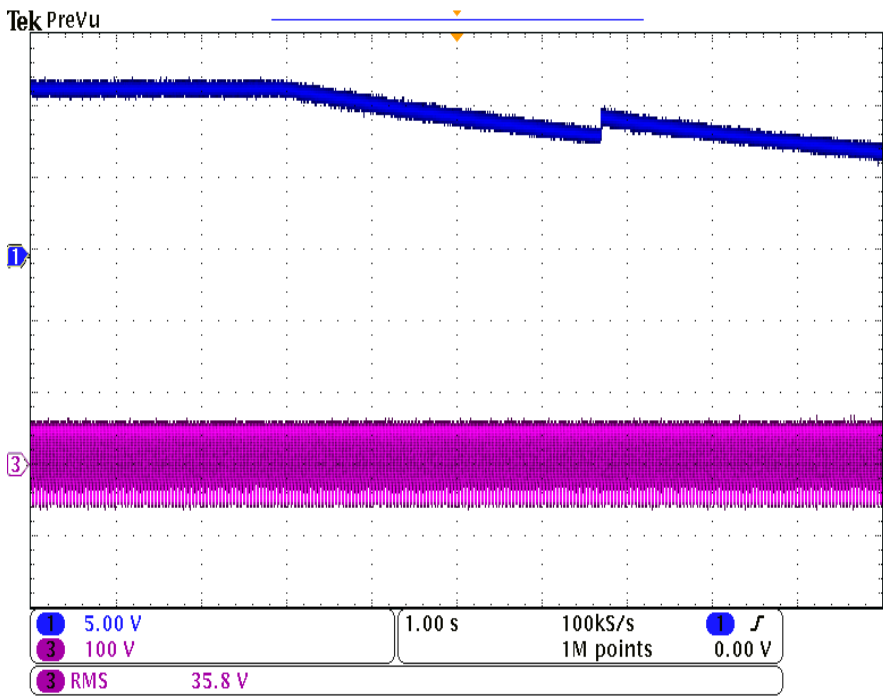
Full Load, $V_{IN_STARTUP}=75.6V_{AC}$



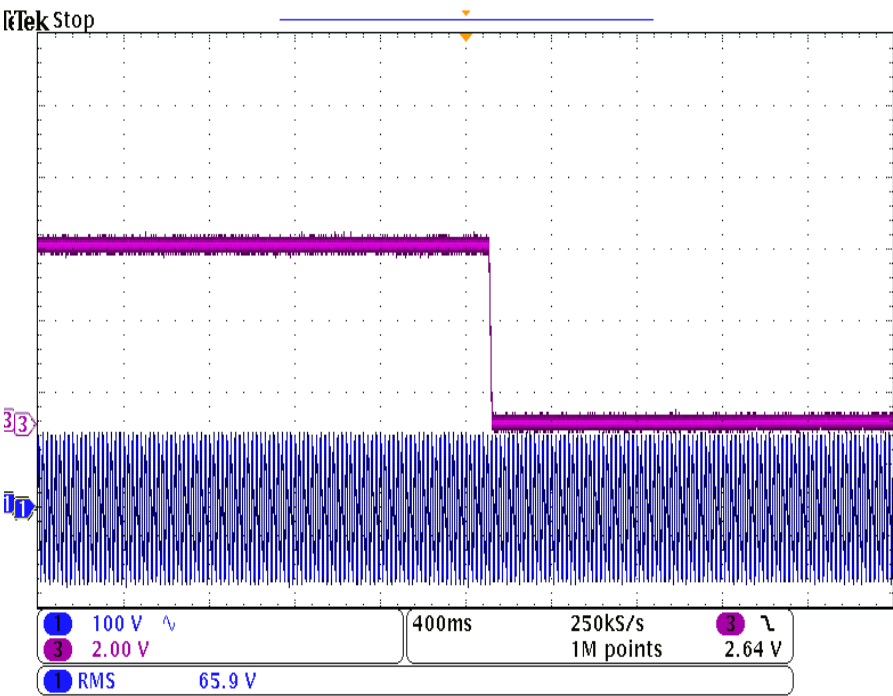
CH1:AC Input CH3:5V

9. AC Brownout Voltage Characteristic

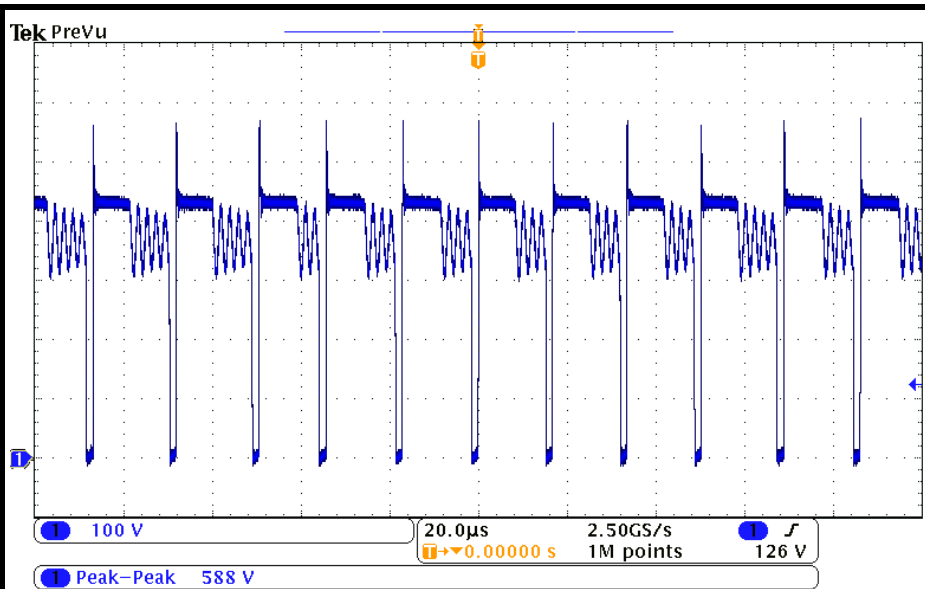
No Load, $V_{IN_BROWNOUT} = 35.8V_{AC}$



Full Load, $V_{IN_BROWNOUT} = 65.9V_{AC}$



10. V_{CE} Waveform



Test Condition:

V_{in}=264Vac, I_{OUT1}=0.25A, I_{OUT2}=0.25A

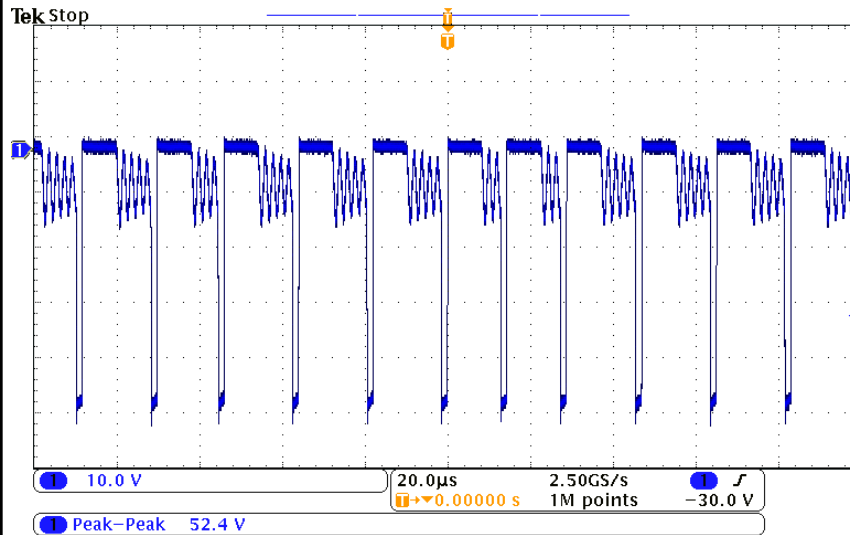
Result:

V_{CE_MAX}=**588V**

iW1812

Parameter Note		Symbol	Rating	Unit
Collector-Base Breakdown Voltage		V _{CBO}	800	V
Collector-Emitter Breakdown Voltage		V _{CEO}	450	V
Emitter-Base Breakdown Voltage		V _{EBO}	9	V
Collector Current		I _C	1.5	A
Power Dissipation	T _a =25°C	P _{tot}	0.8	W
Junction Temperature		T _j	150	°C
Storage Temperature		T _{stg}	-55~150	°C

11. Output Diode(12V)



Test Condition:

$V_{IN}=264V_{AC}$, $I_{OUT(12V)}=250mA$

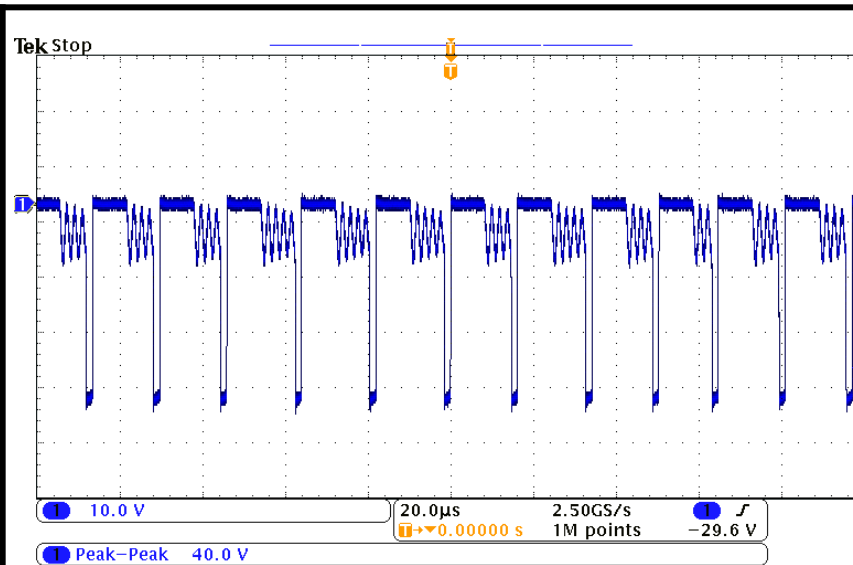
Result:

$V_{D9_PP}=52.4V$

Appendix – Simple Specification for used Diode (HER102)

Type Number	HER 101	HER 102	HER 103	HER 104	HER 105	HER 106	HER 107	HER 108	Units
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T _A = 55°C	1.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	30								A
Maximum Instantaneous Forward Voltage @ 1.0A	1.0				1.3	1.7			V
Maximum DC Reverse Current @ T _A =25°C at Rated DC Blocking Voltage @ T _A =100°C	5.0 100								uA uA
Maximum Reverse Recovery Time (Note 1)	50					75			nS
Typical Junction Capacitance (Note 2)	20					15			pF

12. Output Diode(5V)



Test Condition:

$V_{IN}=264V_{AC}$, $I_{OUT(5V)}=250mA$

Result:

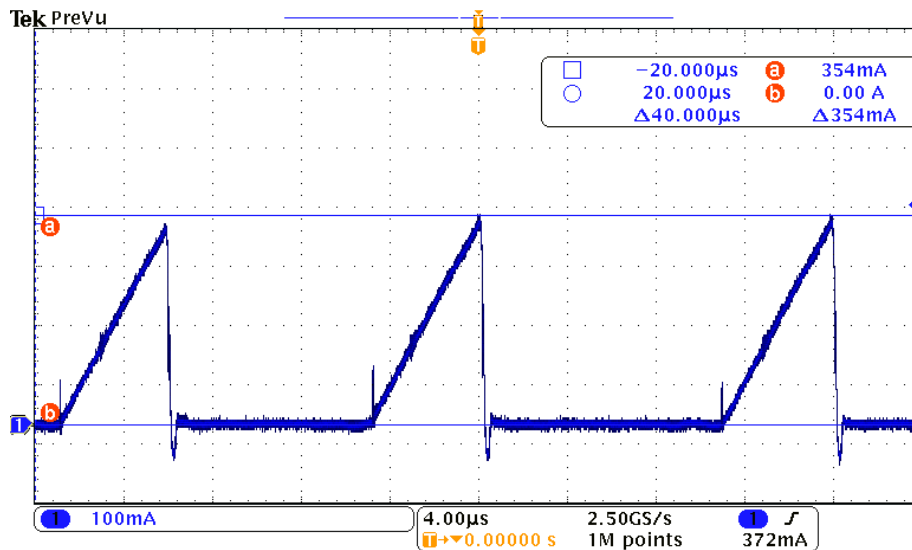
$V_{D1_PP}=40V$

Appendix – Simple Specification for used Schottky Diode (SR260)

Characteristic	Symbol	SR220	SR230	SR240	SR250	SR260	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	20	30	40	50	60	V
RMS Reverse Voltage	$V_R(RMS)$	14	21	28	35	42	V
Average Rectified Output Current (Note 1) @ $T_L = 100^\circ C$	I_o	2.0					A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50					A
Forward Voltage @ $I_F = 2.0A$	V_{FM}	0.50			0.70		V
Peak Reverse Current @ $T_A = 25^\circ C$ At Rated DC Blocking Voltage @ $T_A = 100^\circ C$	I_{RM}	0.5 10					mA

13. Transformer Flux Density

($N_p=126$ Ts, $L_m=1.6$ mH, $A_e=18.5$ mm²-EE1614)



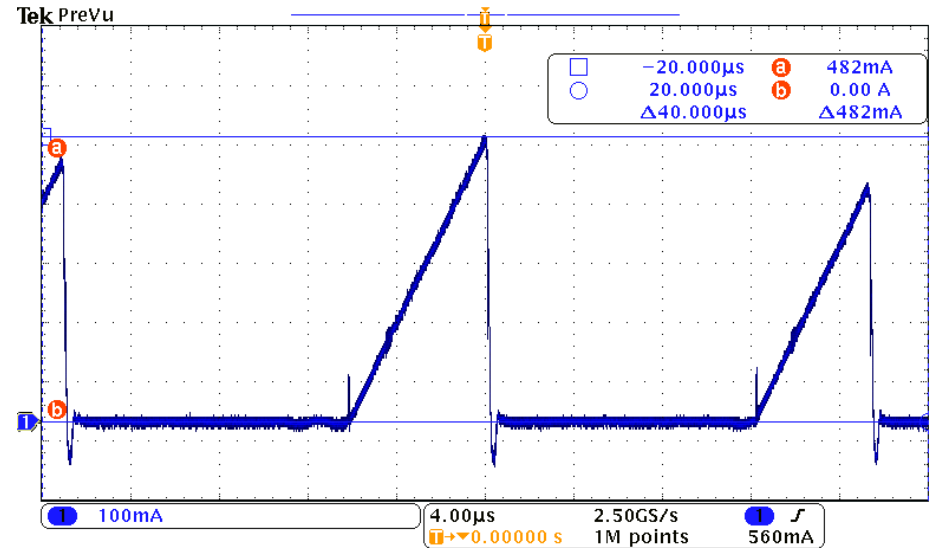
I_{PRI} is monitored at 85Vac and (250+250)mA load

$I_{PRI}=354$ mA

$$B_{MAX} = I_{PRI} * L_{PRI} / (N_P * A_e)$$

$$= (354 * 1.6) / (126 * 18.5)$$

$$= 0.243 \text{ Tesla}$$



I_{PRI} is monitored at 90Vac and (320+320)mA load (Max Output Power).

$I_{PRI}=482$ mA

$$B_{MAX} = I_{PRI} * L_{PRI} / (N_P * A_e)$$

$$= (482 * 1.6) / (126 * 18.5)$$

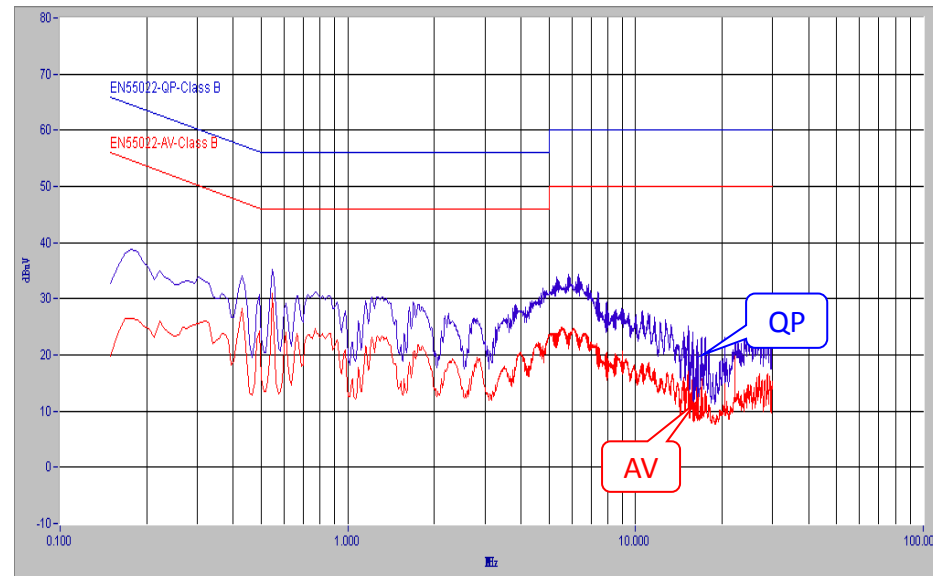
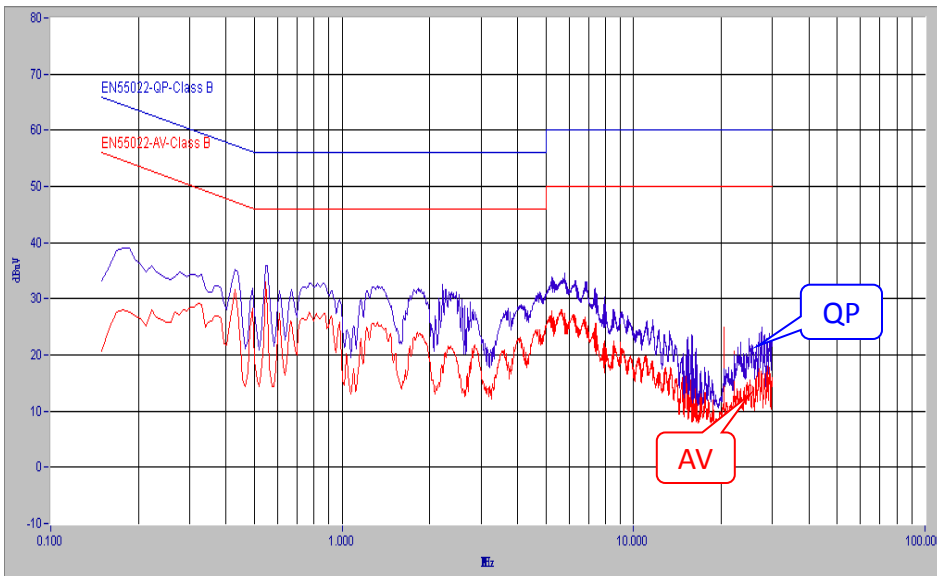
$$= 0.331 \text{ Tesla}$$

[illegible]

15. Conducted EMI

230VAC, Live

230VAC, Neutral



- Note: 1. Vin=230Vac, output is loading resistance-load(Full load)**
2. Input add filter circuit, Output is floating.